# i.MX 8M Mini Hardware Developer's Guide



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# Chapter 1 Overview

This document aims to help the hardware engineers to design and test the i.MX 8M Mini series processors. It provides examples of the board layout and the design checklists to ensure first-pass success, and solutions to avoid board bring-up problems.

Engineers should understand board layouts and board hardware terminology.

This guide is released with relevant device-specific hardware documentation, such as datasheets, reference manuals, and application notes. All these documents are available on Evaluation Kit for the i.MX 8M Mini Applications Processor.

# 1.1 Device supported

This document supports the i.MX 8M Mini (14 x 14 mm package).

#### 1.2 Essential references

This guide is supplementary to the i.MX 8M Mini series chip reference manuals and data sheets, see i.MX 8M Mini - Arm<sup>®</sup> Cortex<sup>®</sup>-A53, Cortex-M4, Audio, Voice, Video. For reflow profile and thermal limits during the soldering, see *General Soldering Temperature Process Guidelines* (document AN3300).

# 1.3 Supplementary references

This section provides the details of the general information, related documentation, conventions, and acronyms and abbreviations.

#### 1.3.1 General information

The following documents introduce the Arm® processor architecture and computer architecture.

- For information about the Arm Cortex<sup>®</sup>-A35 processor, see Cortex-A35
- For information about the Arm Cortex-A53 processor, see Cortex-A53
- For information about the Arm Cortex-A72 processor, see Cortex-A72
- For information about the Arm Cortex-M4F processor, see Cortex-M4
- Computer Architecture: A Quantitative Approach (Fourth Edition) by John L. Hennessy and David A. Patterson
- Computer Organization and Design: The Hardware/Software Interface (Second Edition), by David A. Patterson and John L. Hennessy

The following documentation introduces the high-speed board design:

- Right the First Time- A Practical Handbook on High-Speed PCB and System Design Volumes I and II Lee W. Ritchey (Speeding Edge) - ISBN 0-9741936- 0-72
- Signal and Power Integrity Simplified (2nd Edition) Eric Bogatin (Prentice Hall)- ISBN 0-13-703502-0
- High-Speed Digital Design- A Handbook of Black Magic Howard W. Johnson and Martin Graham (Prentice Hall) ISBN 0-13-395724-1
- High-Speed Signal Propagation- Advanced Black Magic Howard W. Johnson and Martin Graham (Prentice Hall) ISBN 0-13-084408-X
- High-Speed Digital System Design- A handbook of Interconnect Theory and Practice Hall, Hall and McCall (Wiley Interscience 2000) - ISBN 0-36090-2
- Signal Integrity Issues and Printed Circuit Design Doug Brooks (Prentice Hall) ISBN 0-13-141884-X
- PCB Design for Real-World EMI Control Bruce R. Archambeault (Kluwer Academic Publishers Group) ISBN 1-4020-7130-2

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- Digital Design for Interference Specifications A Practical Handbook for EMI Suppression -David L. Terrell and R. Kenneth Keenan (Newnes Publishing) - ISBN 0-7506-7282-X
- Electromagnetic Compatibility Engineering Henry Ott (1st Edition John Wiley and Sons) ISBN 0-471-85068-3
- Introduction to Electromagnetic Compatibility Clayton R. Paul (John Wiley and Sons) ISBN 978-0-470-18930-6
- Grounding and Shielding Techniques Ralph Morrison (5th Edition John Wiley and Sons) ISBN 0-471-24518-6
- EMC for Product Engineers Tim Williams (Newnes Publishing) ISBN 0-7506- 2466-3

#### 1.4 Related documentation

Additional literature is published when the new NXP products become available.

For the list of current documents, see i.MX 8M Mini - Arm® Cortex®-A53, Cortex-M4, Audio, Voice, Video.

#### 1.5 Conventions

Table 1 lists the notational conventions used in this document.

Table 1. Conventions used in this document

Conventions	Description
Courier	Used to indicate commands, command parameters, code examples, and file and directory names.
Italics	Used to indicate command or function parameters.
Bold	Function names are written in bold.
cleared/set	When a bit takes the value zero, it means to be cleared; when it takes a value of one, it means to be set.
mnemonics	Instruction mnemonics are shown in lowercase bold. Book titles in text are set in italics.
sig_name	Internal signals are written in all lowercase.
nnnn nnnnh	Denotes hexadecimal number.
0b	Denotes binary number.
rA, rB	Instruction syntax used to identify a source GPR.
<b>r</b> D	Instruction syntax used to identify a destination GPR.
REG[FIELD]	Abbreviations for registers are shown in uppercase. Specific bits, fields, or ranges appear in brackets. For example, MSR[LE] refers to the little-endian mode enable bit in the machine state register.
х	An italicized <i>x</i> indicates an alphanumeric variable.
n, m	An italicized <i>n</i> indicates a numeric variable.

In this guide, notation for all logical, bit-wise, arithmetic, comparison, and assignment operations follow the "C" language conventions.

# 1.6 Acronyms and abbreviations

Table 2 defines the acronyms and abbreviations used in this document.

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Table 2. Acronyms and abbreviations

Acronym	Definition
ARM	Advanced RISC Machines processor architecture
BGA	Ball Grid Array package
ВОМ	Bill of Materials
BSDL	Boundary Scan Description Language
CAN	Flexible Controller Area Network peripheral
ССМ	Clock Controller Module
CSI	MIPI Camera Serial Interface
DDR	Dual Data Rate DRAM
DDR3L	Low-voltage DDR3 DRAM
DDR4	DDR4 DRAM
DDRC	DDR Controller
DFP	Downstream Facing Port (USB Type-C)
DRP	Dual Role Port (USB Type-C)
ECSPI	Enhanced Configurable SPI peripheral
EIM	External Interface Module
ENET	10/100/1000 Mbps Ethernet MAC peripheral
EPIT	Enhanced Periodic Interrupt Timer peripheral
ESR	Equivalent Series Resistance
GND	Ground
GPC	General Power Controller
GPIO	General Purpose Input/Output
HDCP	High-bandwidth Digital Content Protection
I <sup>2</sup> C	Inter-integrated Circuit interface
IBIS	Input/output Buffer Information Specification
IOMUX	i.MX 8M Mini chip-level I/O multiplexing

Table 2. Acronyms and abbreviations (continued)

Acronym	Definition
JTAG	Joint Test Action Group
KPP	Keypad Port Peripheral
LDB	LVDS Display Bridge
LDO	Low Drop-Out regulator
LPCG	Low-Power Clock Gating
LPDDR4	Low-Power DDR4 DRAM
LVDS	Low-Voltage Differential Signaling
MLB	Media Local Bus
ODT	On-Die Termination
ОТР	One-Time Programmable
РСВ	Printed Circuit Board
PCle	PCI Express
PCI-SIG	Peripheral Component Interconnect Special Interest Group
PDN	Power Distribution Network
PMIC	Power Management Integrated Circuit
POR	Power-On Reset
PTH	Plated Through Hole PCB (that is, no microvias)
RGMII	Reduced Gigabit Media Independent Interface (Ethernet)
RMII	Reduced Media Independent Interface (Ethernet)
ROM	Read-Only Memory

# Chapter 2 i.MX 8M Mini design checklist

This document provides a design checklist for the i.MX 8M Mini (14 x 14 mm package) processor. The design checklist tables recommend optimal design and provide the explanations to help users understand better. For supplemental checklist tables, see Design checklist table.

# 2.1 Design checklist table

Table 3. LPDDR4 recommendations (i.MX 8M Mini)

Check box	No.	Recommendations	Explanation/supplemental recommendations
	1	Connect the DRAM_ZN ball on the processor (ball P2) to 240 ohms, 1 % resistor to GND.	This is a reference used during DRAM output buffer driver calibration.
	2	The ZQ0 and ZQ1 balls on the LPDDR4 device must be connected through 240 ohms, 1 % resistor to the LPDDR4 VDD2 rail.	-
	3	Place a 10 kilohms, 5 % resistor to ground on the DRAM reset signal.	This ensures adherence to the JEDEC specification until the control is configured and starts driving the DDR.
	4	The ODT_CA balls on the LPDDR4 device must be connected directly to the LPDDR4 VDD2 rail.	The LPDDR4 ODT on the i.MX 8M Mini is command-based, making the processor ODT_CA output balls unnecessary.
	5	The architecture for each chip inside the DRAM package must be x 16.	The processor does not support byte mode specified in JESD209-4B.
	6	The processor ball MTEST (ball N2), must be left unconnected.	These are observability ports for manufacturing and are not used otherwise.
	7	The VREF pin on the processor (ball P1) can be left unconnected.	The VREF signal for LPDDR4 is generated internally by the processor.
	8	If 16-bit LPDDR4 memory device is used, the signals must only be connected to channel A of I.MX8M Mini DDR controller, the reference design of 8MMINILPD4- EVK cannot be used.	On 8MMINILPD4- EVK, 32-bit LPDDR4 Memory Channel A/B are swapped for easier signal routing.
	9	It is suggested using LPDDR4 if lower-power consumption is required because the DLL-off mode is not supported.	The LPDDR4 can operate at a low frequency without the DLL-off mode.

Table 4. DDR4/DDR3L recommendations (i.MX 8M Mini)

Check box	No.	Recommendations	Explanation/supplemental recommendations
	1	Connect the ZQ (DRAM_ZN) ball on the processor (ball P2) to individual 240 ohms, 1 % resistor to GND.	This is a reference used during DRAM output buffer driver calibration.

Table 4. DDR4/DDR3L recommendations (i.MX 8M Mini) (continued)

Check box	No.	Recommendations	Explanation/supplemental recommendations
	2	The ZQ ball on each DDR4/DDR3L device must be connected through individual 240 ohms, 1 % resistor to GND.	-
	3	Place a 10 kilohms, 5 % resistor to ground on the DRAM reset signal.	This ensures adherence to the JEDEC specification until the control is configured and starts driving the DDR.
	4	The processor ball MTEST (ball N2), must be left unconnected.	These are observability ports for manufacturing and are not used otherwise.
	5	The DLL-off mode is not supported, which means that DDR4/DDR3L cannot run in a low frequency, such as 100MTS.	The power consumption for the low-power mode in a DDR4/DDR3L system is higher than that of an LPDDR4 system.

#### Table 5. GPIO recommendations

Check box	No.	Recommendations	Explanation/supplemental recommendations
	1	Use external resistors in 3.3 V mode if pull-up/down is needed.	IO internal pull-up/down is not supported in 3.3 V mode. Users must disable the internal pull-up/down through software and use external pull-up/down resistors instead.
			All IO pin groups are impacted except for XTAL, DDR, PCI, USB, and MIPI PHY IO's.
			For details, see, errata e50080 for detailed information.
	2	Disable internal pull-up/down by software.	Disable the internal pull-up/down by setting PAD control register PE bit (pull resistors enable field) to 0. For example, disable this bit in initialization code or DTB under Linux OS.

# Table 6. I<sup>2</sup>C recommendations

Check box	No.	Recommendations	Explanation/supplemental recommendations
	1	Verify the target I <sup>2</sup> C interface clock rates.	The I <sup>2</sup> C bus can only be operated as fast as the slowest peripheral on the bus. If faster operation is required, move the slow devices to another I <sup>2</sup> C port.
	2	Verify that there are no I <sup>2</sup> C address conflicts on any of the I <sup>2</sup> C buses utilized.	There are multiple I <sup>2</sup> C ports available on-chip, so if a conflict exists, move one of the conflicting devices to a different I <sup>2</sup> C bus. If it is impossible, use an I <sup>2</sup> C bus switch (NXP part number PCA9646, see <i>Buffered 4-channel 2-wire bus switch</i> (document PCA9646).

Table 6. I<sup>2</sup>C recommendations (continued)

Check box	No.	Recommendations	Explanation/supplemental recommendations
	3	Do not place more than one set of pull-up resistors on the I <sup>2</sup> C lines.	This could result in excessive loading and potential incorrect operation. Choose the pull-up value commensurate with the bus speed being used.
	4	Ensure that the VCC rail powering the i.MX 8M Mini I <sup>2</sup> C interface balls matches the supply voltage used for the pull-up resistors and the slave I <sup>2</sup> C devices.	Prevent device damage or incorrect operation due to voltage mismatch.

Table 7. JTAG recommendations

Check box	No.	Recommendations	Explanation/supplemental recommendations
	1	Do not use external pullup or pulldown resistors on JTAG_TDO.	JTAG_TDO is configured with an on-chip keeper circuit, and the floating condition is actively eliminated.
	2	Follow the recommendations for external pull-up and pull-down resistors given in Table 17.	-
	3	For normal operation, TEST_MODE (ball D26) must be pulled down using a 100 kilohms resistor. To enter boundary-scan mode, this pin must be pulled up to NVCC_JTAG using a 4.7 kilohms resistor. Reference "COMPLIANCE_PATTERNS" in the chip BSDL file.	-
	4	JTAG_MOD must be connected to the ground through a resistor.	-

Table 8. Reset and ON/OFF recommendations

Check box	No.	Recommendations	Explanation/supplemental recommendations
	1	The POR_B input must be asserted at powered up and remain asserted until the last power rail for devices required for system boot are at their working voltage. This functionality is controlled by the PMIC (PCA9450AAHN) on EVK.	POR_B is driven by the PMIC. If a reset button is used, it must be connected to the PMIC_RST_B pin of the PMIC instead of directly connected to POR_B pin of the CPU. When POR_B is asserted (low) on the i.MX 8M Mini, the output PMIC_ON_REQ remains asserted (high).
	2	For portable applications, the ON/OFF pin may be connected to an ON/OFF SPST pushbutton switch to ground. An external pull-up resistor is required on this pin.	A brief connection to GND in OFF mode causes the internal power management state machine to change state to ON. In ON mode, a brief connection to GND generates an interrupt (intended to initiate a software-controllable power-down). The connection to GND for approximate 5 seconds or more causes a forced OFF.
	3	Connect GPIO1_IO02 (WDOG_B, ball AG13) to external PMIC or reset IC to repower the system except SNVS is recommended.	i.MX8M Mini cannot be reset by internal reset source in idle mode, repower is preferred. Some

Table 8. Reset and ON/OFF recommendations (continued)

Check box	No.	Recommendations	Explanation/supplemental recommendations		
			peripherals like SD3.0, QSPI also need repower during system reset.		
	4	GPIO1_IO02 (WDOG_B, ball AG13) is used as Cold Reset, external pull-up resistor (100 kilohms) must support boundary-scan mode.	In boundary scan mode, WDOG_B is floating. Without the external 100 kilohms pull-up, WDOG_B repeatedly resets 8MMINILPD4- EVK when entering boundary-scan mode.		

# Table 9. PCle recommendations

Check box	No.	Recommendations	Explanation/supplemental recommendations
	1	Use an appropriate external PCIe reference clock generator.	The NXP EVK board design uses an IDT 9FGV0241 device. However, NXP does not recommend one supplier over another, and does not suggest that this is the only clock generator supplier. The used device must support all the specs (jitter, accuracy, and so on).
	2	The differential transmitters from the processor must be AC coupled. It is recommended to use a 0.1 µF cap on both the PCIE_TXP and PCIE_TXN outputs.	PCIe specification compliance requires AC coupling at each transmitter. The receiver must be DC coupled.
	3	The PCIEx_RESREF ball (ball D19) must be connected to the ground through a 8.2 kilohms, 1 % resistor.	-

# Table 10. USB recommendations

Check box	No.	Recommendations	Explanation/supplemental recommendations	
	1	Connect a 200 ohms, 1 % resistor to the ground on the USBx_TXRTUNE ball (ball E19 and E22).	-	
	2	Route all USB differential signals with 90 ohms differential impedance.	-	
	3	ESD protection must be implemented at the connector pins. Choose a low capacitance device recommended for high-speed interfaces.	This prevents potential damages to board components from ESD.	

#### Table 11. FlexSPI recommendations

Check box	Recommendations	Explanation/supplemental recommendations
	Read strobe (DQS) pad must be floated or with a 10-18 pF cap load to compensate SIO/SCK pins load for high speed running, if the memory device does not provide DQS.	There are three modes for the internal sample clock for FlexSPI read data:

Table 11. FlexSPI recommendations

Check box	Recommendations	Explanation/supplemental recommendations
		Dummy read strobe generated by FlexSPI controller and looped back internally (FlexSPIn_MCR0[RXCLKSRC] = 0x0), can only reach 66 MHz operation frequency.
		Dummy read strobe generated by FlexSPI controller and looped back through the DQS pad (FlexSPIn_MCR0[RXCLKSRC] = 0x1), can reach 133 MHz operation frequency. In this mode, this pin can be floated or put some cap loads on board level to compensate SIO/SCK pins load.
		<ul> <li>Read strobe provided by memory device and input from DQS pad (FlexSPIn_MCR0[RXCLKSRC] = 0x3), can reach 133 MHz operation frequency.</li> </ul>

Table 12. Oscillator/crystal recommendations

Check box	No.	Recommendations	Explanation/supplemental recommendations
	1	Connect a 24 MHz crystal and a 510 kilohms resistor between 24M_XTALI and 24M_XTALO (balls B27 and C26).	This crystal must have ESR not greater than 80 ohms, and be rated for a drive level of at least 180 µW. Follow the manufacturer's recommendation for loading capacitance. Use short traces between the crystal and the processor, with a ground plane under the crystal, load capacitors, and associated traces.
	2	Use the 32.768 kHz clock generated by the PMIC (PCA9450AAHN) to drive the i.MX 8M Mini RTC_XTALI input (ball A26), and connect RTC_XTALO (ball B25) to VDD_SNVS_0P8.	The voltage level of this driving clock must not exceed the voltage of the NVCC_SNVS rail, or the damage/malfunction may occur. The RTC signal must not be driven if the NVCC_SNVS supply is OFF. It can lead to damage or malfunction. For RTC V <sub>IL</sub> and V <sub>IH</sub> voltage levels, see the latest i.MX 8M Mini data sheet available at i.MX 8M Mini - Arm® Cortex®-A53, Cortex-M4, Audio, Voice, Video.

Table 13. i.MX 8M Mini power/decoupling recommendations

Check box	No.	Recommendations	Explanation/supplemental recommendations
	1	Comply with the power-up sequence guidelines as described in the data sheet to guarantee reliable operations of the device.	Any deviation from these sequences may result in the following situations:  • Excessive current during power-up phase  • Prevention of the device from booting

Table 13. i.MX 8M Mini power/decoupling recommendations (continued)

Check box	No.	Recommendations	Explanation/supplemental recommendations		
			Irreversible damage to the processor (worst case)		
	2	Maximum ripple voltage requirements	Common requirement for ripple noise peak-to- peak value must be less than 5 % of the supply voltage nominal value.		
	3	If using PCA9450A PMIC to provide power, make sure that the voltage-sensing pin of each BUCK is tied to INBxx PIN of BUCK and Leave LXx floating if unused.	The voltage-sensing pins are R_SNSP3_CFG, R_SNSPx, and BUCKxFB in the PCA9450A. Leaving any BUCK output open, the PMIC enters into fault, shutdown.		
	4	Check the PMIC switcher output currents and the switcher inductor current ratings against the maximum supply currents ratings per rail, as specified within the data sheet.	When using a non-NXP PMIC or scaling down a power rail, make sure that the PMIC and inductor meet the maximum current demands of the system.		
			Note: The currents are higher for the SoC temperatures higher than the room temperature.		

Table 14. Decoupling capacitors recommendations (i.MX 8M Mini)

Check box	Supply	2.2 nF	0.22 μF	1 μF	4.7 μF	10 µF	Note
	VDD_DRAM, VDD_VPU, VDD_GPU, VDD_DRAM_PLL_0P8	-	-	6	-	2	These 4 power rails are combined together on EVK
	NVCC_DRAM	-	-	6	-	2	-
	VDD_ARM	-	-	5	-	1	-
	VDD_SOC	-	-	5	-	1	-
	VDD_SNVS_0P8	-	1	-	-	-	-
	NVCC_SNVS_1P8	-	-	1	-	-	-
	VDD_24M_XTAL_1P8	-	1	-	-	-	-
	VDD_DRAM_PLL_1P8	-	-	1	-	-	-
	PVCC_1P8	-	2	-	-	-	-
	VDD_ARM_PLL_1P8, VDD_ANA0_1P8, VDD_ANA1_1P8,	-	4	-	-	1	-

Table 14. Decoupling capacitors recommendations (i.MX 8M Mini) (continued)

Check box	Supply	2.2 nF	0.22 µF	1 µF	4.7 µF	10 µF	Note
	VDD_USB_1P8, VDD_PCI_1P8, VDD_MIPI_1P8						
	NVCC_SAI1, NVCC_SAI3, NVCC_SAI5, NVCC_ECSPI, VDD_USB_3P3	-	4	-	1	-	-
	NVCC_JTAG, NVCC_SAI2, NVCC_GPIO1, NVCC_I2C, NVCC_UART, NVCC_SD1, NVCC_CLK, NVCC_NAND	-	3	-	-	1	-
	NVCC_SD2	-	1	-	-	-	-
	NVCC_ENET	-	1	-	-	-	-
	VDD_ARM_PLL_0P8, VDD_ANA_0P8, VDD_USB_0P8, VDD_PCI_0P8	-	1	-	1	-	-
	VDD_MIPI_1P2	-	1	-	-	-	-
	VDD_MIPI_0P9	-	1	-	-	-	-
	MIPI_VREG_CAP	1	-	-	-	-	-
	1						l

# Capacitor part number used on EVK:

- 2.2 nF GRM033R71C222KA88D
- 0.22 µF LMK063BJ224MP-F
- 1 μF 02016D105MAT2A
- 4.7 µF CL05A475KP5NRNC
- 10 μF ZRB15XR60J106ME12D

Table 15. PCB design recommendations

Check box	No.	Recommendations	Explanation/supplemental recommendations
	1	High-speed signal traces have reference plane in adjacent layer and are impedance controlled.	Controlled impedance is the key factor to have good signal integrity.
			<b>Note:</b> The reference plane can only be GND or the signal's own I/O power. Do not use other nets as reference.
	2	High-speed signal traces never cross gap or slot in reference plane.	Crossing gap in reference plane causes reflection and increase crosstalk.
	3	Place at least one GND stitching via within 50 mils of signal via when switching reference planes.	GND stitching via can help keep impedance continuous and reduce via crosstalk.
			Signals within a bus must have delay time matched to maintain timing margin.
	The true and complementary signal of a differential pair must have delay matched to within 1 ps.		The true and complementary signal within a differential pair must have delay time tightly matched.
	6	DDR interface passed SI simulation. Alternatively, directly copy the EVK DDR layout design.	Generally, SI simulation must be performed for DDR interface that runs at 3000 MT/s to ensure stable working. If this is not feasible, copy the EVK DDR layout design as well as the board stack-up.
	7	Place test point on key signals to ease debugging. When placing test point on high-speed signal traces, make sure that it's diameter is not more than 20 mil and the test point be directly placed on the trace with no stub.	Test points can bring excessive capacitance and must be carefully handled on high-speed signal traces.
	8	Decoupling capacitors are placed as close to IC power pins as possible.	This is to reduce the inductance from decoupling capacitor to IC power pin, to improve decoupling effectiveness.
	9	Recommend the Non-Solder Mask Defined (NSMD) land pad for PCB.	For NSMD pad design requirement, see <i>PCB layout guidelines for NXP MCUs in BGA packages</i> (document AN10778)

# 2.2 JTAG signal termination

Table 16 is a JTAG termination chart, it lists what terminations should be placed on PCB designs.

Table 16. Recommended JTAG board terminations

JTAG signal	I/O type	External termination	Comments
JTAG_TCK	Input	10 kilohms pull-down	-
JTAG_TMS	Input	None	Internal pulled up to NVCC_JTAG, no external termination required

Table 16. Recommended JTAG board terminations (continued)

JTAG signal	I/O type	External termination	Comments
JTAG_TDI	Input	None	Internal pulled up to NVCC_JTAG, no external termination required
JTAG_TDO	3-state output	None	-
JTAG_TRSTB	Input	None	No connection from JTAG to processor, internal pulled up to NVCC_JTAG

# 2.3 Signal termination for Boundary-scan

Table 17 is a signal termination chart showing what terminations should be placed on board designs to support Boundary-scan.

Table 17. Recommended board terminations for Boundary-scan

Signal	I/O type	External termination	Comments
BOOT_MODE0	Input	Pull-up	BOOT_MODE0, BOOT_MODE1, JTAG_MOD, and TEST_MODE must be at
BOOT_MODE1	Input	Pull-up	1101 to enter in Boundary-scan mode.
JTAG_MOD	Input	Pull-down	
TEST_MODE	Input	Pull-up	
GPIO1_IO02 (WDOG_B)	Input	Pull-up	External pull up resistor (100 Kilohms) must support boundary-scan mode.

#### 2.4 General recommendations

More than one software operating environment can run on the i.MX 8M Mini platforms concurrently. The peripherals on these SoCs are accessible to all software operating environments. A conflict occurs when more than one software operating environment reads or writes the state of the same peripheral. Therefore, the software operating environments must be isolated from each other when accessing shared resources. For example, if two operating environments read from and write to the same region of DRAM without coordinating their access, the results are unpredictable. The same behavior is applicable for peripheral registers, especially for the IP modules which offer multiple logical channels, such as GPIO, I<sup>2</sup>C, SPI, SAI, DMA.

Therefore, any sharing of an IP module between Cortex®-M and Cortex®-A domains must be coordinated with the system software architecture because software operating environments must be isolated from each other when accessing shared resources to avoid safety/reliability issues.

Consider a specific example: Individual GPIO pins are aggregated into groups and each group is controlled by a single GPIO module. Each GPIO module is a distinct peripheral that must be protected from conflicting access by different software operating environments. For example, a GPIO1 module is assigned as a shared peripheral for the Linux OS on the Cortex-A and for the FreeRTOS on the Cortex-M. Cortex-A and Cortex-M should obtain a semaphore lock before the access to any GPIO1 module pin is allowed. If Cortex-A and Cortex-M attempt to access the GPIO1 module at the same time, it can result in the lack of isolation leading to safety/reliability issues.

> NOTE The resource allocation should assure any peripheral that has external signals pinned out and, its IO resource can be synchronously controlled by Cortex-A or Cortex-M in the corresponding software operating environment.

Not allocating correctly can result in the lack of isolation, leading to safety/reliability issues that can only be overcome with complex software, such as virtual drivers which can indirectly affect the hardware isolation of the software domains and the peripheral performance. In this case, implement customized software solutions, such as the RPMSG client/server-style cooperative device drivers or the peripheral exclusive access using a Mutex solution implemented using SEMA42. The implementation on the i.MX 8M Mini is up to the customer software architecture.

Under those circumstances, the peripheral modules must be allocated to the software systems per a module basis and not per a signal basis from the board design phase.

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# Chapter 3 i.MX 8M Mini layout/routing recommendations

#### 3.1 Introduction

This chapter describes how to assist design engineers with the layout of an i.MX 8M Mini-based system.

# 3.2 Basic design recommendations

When using the Allegro design tool, the schematic symbol and PCB footprint created by NXP are recommended. When not using the Allegro tool, use the Allegro footprint export feature (supported by many tools). If the export is not possible, create the footprint as per the package dimensions outlined in the product data sheet.

Native Allegro layout and gerber files are available on the Evaluation Kit for the i.MX 8M Mini Applications Processor.

### 3.2.1 Placing decoupling capacitors

Place small decoupling and larger bulk capacitors on the bottom side of the PCB.

The 0201 or 0402 decoupling and 0603 or larger bulk capacitors should be mounted as close as possible to the power vias. The distance should be lesser than 50 mils. Additionally bulk capacitors can be placed near the edge of the BGA via array. Placing the decoupling capacitors close to the power balls is critical to minimize inductance and ensure high-speed transient current required by the processor. See the i.MX 8M Mini EVK layouts on i.MX 8M Mini - Arm® Cortex®-A53, Cortex-M4, Audio, Voice, Video for examples of the desired decoupling capacitor placement.

The following action describes how to choose the correct decoupling scheme:

- 1. Place the largest capacitance in the smallest package so that the budget and manufacturing can support it.
- 2. For high speed bypassing, select the required capacitance with the smallest package, for example, 0.1  $\mu$ F, 0.22  $\mu$ F, 1.0  $\mu$ F, or even 2.2  $\mu$ F in a 0201 package size.
- 3. Minimize the trace length (inductance) to small caps.
- 4. Series inductance cancel-out capacitance.
- 5. Tie caps to the GND plane directly with a via.
- 6. Place capacitors close to the power ball of the associated package from the schematic.

A preferred BGA power decoupling design is available on the EVK board design, see Evaluation Kit for the i.MX 8M Mini Applications Processor. Customers must use the NXP design strategy for power and decoupling.

# 3.3 Stack-up and manufacturing recommendations

#### 3.3.1 Stack-up recommendation (i.MX 8M Mini)

Due to the number of balls on the i.MX 8M Mini processor in the 14 mm x 14 mm package, a minimum 8-layer PCB stack-up is recommended. For the 8-layers on the PCB, enough layers must be dedicated to power on routing to meet the IR drop target of 2 % for the i.MX 8M Mini CPU power rails.

The constraints for the trace width depend on such factors as the board stack-up, associated dielectric, copper thickness, required impedance, and required current (for power traces). The stack-up also determines the constraints for routing and spacing. Consider the following requirements when designing the stack-up and selecting board material:

- · Board stack-up is critical for high-speed signal quality.
- Pre-planning impedance of critical traces is required.
- High-speed signals must have the reference planes on adjacent layers to minimize crosstalk.

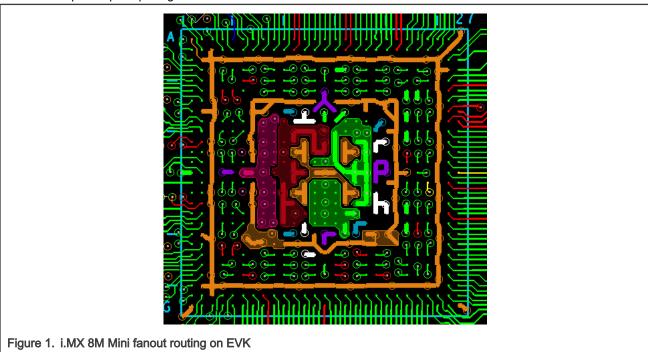
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• PCB material: the material used on EVK is TU768.

# 3.3.2 Manufacturing recommendation (i.MX 8M Mini)

Since the i.MX 8M Mini processor uses a 0.5 mm-pitch BGA package, the PCB technology must meet the requirement given below to fully fanout all the signals of the processor using PTH (plated through holes).

- · Minimum trace width: 3.2 mil
- · Minimum trace to trace/pad spacing: 3.2 mil
- · Minimum via size: 8 mil-diameter hole, 16 mil-diameter pad
- · Minimum via pad-to-pad spacing: 4 mil



For the reference routing of the i.MX 8M Mini, see Figure 1. PTH is OK for the fanout, however, HDI is not needed.

#### 3.3.3 EVK PCB stack-up (i.MX 8M Mini)

Table 18 and Table 19 lists the stack-up of the EVK. Both the CPU board and the BB board use 8-layer stack-up.

Table 18. 8MMINILPD4-CPU Board stack up information

Layer	Description	Copper (Oz.)	Dielectric thickness (mil)
1	Signal	0.333 + Plating	-
	Dielectric	-	2.77 mil
2	GND	1	-
	Dielectric	-	3.94 mil
3	Signal	1	-

Table continues on the next page...

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Table 18. 8MMINILPD4-CPU Board stack up information (continued)

Layer	Description	Copper (Oz.)	Dielectric thickness (mil)
	Dielectric	-	5.04 mil
4	GND	1	-
	Dielectric	-	12 mil
5	Power	1	-
	Dielectric	-	5.54 mil
6	Power	1	-
	Dielectric	-	3.94 mil
7	GND	1	-
	Dielectric	-	2.77 mil
8	Signal	0.333+Plating	-
Finished thickness:	47.244(4.724/-4.724) mil		1.2(+0.12/-0.12) MM
Material:	TU768		TU768

Table 19. 8MMINI-BB Board stack up information

Layer	Description	Copper (Oz.)	Dielectric thickness (mil)
1	Signal	0.5+Plating	-
	Dielectric	-	2.77 mil
2	GND	1	-
	Dielectric	-	4.33 mil
3	Signal	1	-
	Dielectric	-	12.89 mil
4	Power	1	-
	Dielectric	-	11.81 mil
5	Power	1	-
	Dielectric	-	12.89 mil
6	Signal	1	-

Table 19. 8MMINI-BB Board stack up information (continued)

Layer	Description	Copper (Oz.)	Dielectric thickness (mil)
	Dielectric	-	4.33 mil
7	GND	1	-
	Dielectric	-	2.77 mil
8	Signal	0.5+Plating	-
Finished thickness:	62.992(6.299/-6.299) mil		1.6(+0.16/-0.16) MM
Material:	TU768		TU768

# 3.4 DDR design recommendations

#### 3.4.1 DDR connection information

The i.MX 8M Mini processor can be used with LPDDR4, DDR4, or DDR3L memory. Since these memory types have different I/O signals, there are 38 generically named functional balls, depending on the type of memory used. For the connectivity of the generic balls for DDR3L, LPDDR4, and DDR4, see Table 20. The schematic symbol created by NXP replaces these generic names with the DDR function.

Table 20. DDR3L/LPDDR4/DDR4 connectivity

Ball name	Ball #	LPDDR4 function	DDR4 function	DDR3L function
DRAM_AC00	F4	CKE0_A	CKE0	CKE0
DRAM_AC01	F5	CKE1_A	CKE1	CKE1
DRAM_AC02	K4	CS0_A	CS0_n	CS0#
DRAM_AC03	J4	CS1_A	CO	-
DRAM_AC04	L2	CK_t_A	BG0	BA2
DRAM_AC05	L1	CK_c_A	BG1	A14
DRAM_AC06	F6	-	ACT_n	A15
DRAM_AC07	J5	-	A9	A9
DRAM_AC08	J6	CA0_A	A12	A12/BC#
DRAM_AC09	K6	CA1_A	A11	A11
DRAM_AC10	E4	CA2_A	A7	A7
DRAM_AC11	D5	CA3_A	A8	A8
DRAM_AC12	N4	CA4_A	A6	A6

Table continues on the next page...

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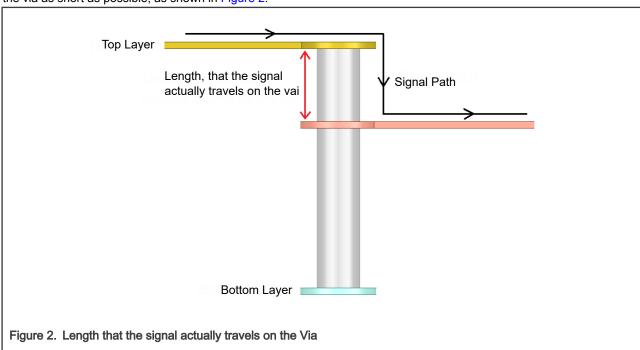
Table 20. DDR3L/LPDDR4/DDR4 connectivity (continued)

Ball name	Ball #	LPDDR4 function	DDR4 function	DDR3L function
DRAM_AC13	N5	CA5_A	A5	A5
DRAM_AC14	K5	-	A4	A4
DRAM_AC15	N6	-	A3	A3
DRAM_AC16	M1	-	CK_t_A	CK_A
DRAM_AC17	M2	-	CK_c_A	CK#_A
DRAM_AC19	N2	MTEST	MTEST	MTEST
DRAM_AC20	AB4	CKE0_B	CK_t_B	CK_B
DRAM_AC21	AB5	CKE1_B	CK_c_B	CK#_B
DRAM_AC22	W4	CS1_B	-	-
DRAM_AC23	V4	CS0_B	-	-
DRAM_AC24	U2	CK_t_B	A2	A2
DRAM_AC25	U1	CK_c_B	A1	A1
DRAM_AC26	N1	-	BA1	BA1
DRAM_AC27	R6	-	PARITY	-
DRAM_AC28	W6	CA0_B	A13	A13
DRAM_AC29	V6	CA1_B	BA0	BA0
DRAM_AC30	AC4	CA2_B	A10 / AP	A10 / AP
DRAM_AC31	AD5	CA3_B	A0	A0
DRAM_AC32	R4	CA4_B	C2	-
DRAM_AC33	R5	CA5_B	CAS_n / A15	CAS#
DRAM_AC34	T1	-	WE_n / A14	WE#
DRAM_AC35	T2	-	RAS_n / A16	RAS#
DRAM_AC36	V5	-	ODT0	ODT0
DRAM_AC37	W5	-	ODT1	ODT1
DRAM_AC38	AB6	-	CS1_n	CS1#

#### 3.4.2 LPDDR4-3000 design recommendations

The following list provides some generic guidelines that should be adhered to when implementing an i.MX 8M Mini design using LPDDR4.

- 1. It is expected that the layout engineer and design team already have experience and training with DDR designs at speeds of 1.5 GHz / 3000 MT/s.
- 2. Refer to the solid GND plane only for all the high-speed signal traces.
- Keep edge-to-edge spacing of high-speed signal traces no less than two times the trace width to minimize trace crosstalk.
- 4. At speed of 3000 MT/s, signal vias can be a significant source of crosstalk. If not properly designed, it can introduce crosstalk larger than that from the trace. To minimize via crosstalk, make sure that the total number of vias to be two or less on each point-to-point single-ended/differential trace. Place at least one ground-stitching via within 50 mils of the signal via when switching reference planes to provide a continuous return path and reduce crosstalk. If it is not possible to place enough ground-stitching vias due to space limitation, try to make the length that the signal actually travels on the via as short as possible, as shown in Figure 2.



- 5. CLK and DQS signals can be routed on a different layer with DQ/CA signals to ease routing. When doing this, keep not less than 5 times trace width spacing from other signals.
- 6. Use time delay instead of length when performing the delay matching. The delay matching includes the PCB trace delay and the IC package delay. Incorporate the package pin delay into the CAD tool's constraint manager.
- 7. Include the delay of vias when performing delay matching. This can be realized in the Allegro tool by enabling the "Z-Axis Delay" in "Setup > Constraints > Modes".
- 8. Byte swapping within each 16-bit channel is OK. Bit swapping within each slice/byte lane is OK.
- 9. Bit swapping of Command/Address (CA[5:0]) signal is not allowed.
- 10. i.MX 8M Mini does not drive ODT\_CA signal. The ODT\_CA balls on the LPDDR4 devices should be connected directly or through a resistor to the VDD2 supply.
- 11. The 200-ball LPDDR4 package must be placed 200 mils from the i.MX 8M Mini.
- 12. Enable the Data Bus Inversion (DBI) feature. It can help reduce both power consumption and power noise.

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#### 3.4.2.1 i.MX 8M Mini LPDDR4-3000 routing recommendations

LPDDR4-3000 must be routed with signal fly times and must match with Table 21. The delay of the via transitions must be included in the overall calculation. This can be realized in the Allegro tool by enabling the "Z-Axis Delay" in "Setup > Constraints > Modes".

An example of the delay match calculation for the i.MX 8M Mini EVK board design is listed in Table 22 and Table 23. This analysis was done for the LPDDR4-3000 implementation using the i.MX 8M Mini. In Table 22 and Table 23, the "PCB delay" column is obtained directly from the Allegro PCB file, and the "Pkg delay" column is the package delay obtained from Table 31.

NXP recommends that users simulate their LPDDR4 implementation before fabricating PCBs.

Table 21. i.MX 8M Mini LPDDR4-3000 routing recommendations

	LPDDR4-3000				
LPDDR4 signal (each 16-	Group	PCB + package prop	delay		
bit channel)		Min	Max	Considerations	
CK_t/CK_c	Clock	Short as possible	200 ps	Match the true/ complement signals within 1 ps.	
CA[5:0]	Address/ Command/ Control	CK_t - 25 ps	CK_t + 25 ps	-	
CS[1:0]	Command/ Common				
CKE[1:0]					
DQS0_t/DQS0_c	Byte 0 - DQS	CK_t - 85 ps	CK_t + 85 ps	Match the true/	
DM0	Byte 0 - Data	DQS0_t -10 ps	DQS0_t +10 ps	complement signals of DQS within 1 ps.	
DQ[7:0]					
DQS1_t/DQS1_c	Byte 1 - DQS	CK_t - 85 ps	CK_t + 85 ps		
DM1	Byte 1 - Data	DQS1_t -10 ps	DQS1_t +10 ps		
DQ[15:8]					

Table 22. LPDDR4 delay matching example (CA/CTL signals)

Net name	PCB delay (ps)	Pkg delay (ps)	Comments
DRAM_CK_T_A	140.1	41.1	Vias are L1 > L8 >L1
	181.2		Total net delay
DRAM_CK_C_A	140.4	41.2	Vias are L1 > L8 >L1
	181.6		Total net delay
DRAM_CA0_A	142.8	39.6	Vias are L1 > L3 > L1
	182.4		Total net delay

Table continues on the next page...

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Table 22. LPDDR4 delay matching example (CA/CTL signals) (continued)

Net name	PCB delay (ps)	Pkg delay (ps)	Comments
DRAM_CA1_A	148.2	29.1	Vias are L1 > L3 > L1
	177.3		Total net delay
DRAM_CA2_A	131.2	54.8	Vias are L1 > L3 > L1
	186.0		Total net delay
DRAM_CA3_A	126.7	59.7	Vias are L1 > L3 > L1
	186.4		Total net delay
DRAM_CA4_A	145.9	33.8	Vias are L1 > L3 > L1
	179.7		Total net delay
DRAM_CA5_A	145.7	32.0	Vias are L1 > L3 > L1
	177.7		Total net delay
DRAM_nCS0_A	145.5	35.9	Vias are L1 > L3 > L1
	181.4		Total net delay
DRAM_nCS1_A	138.1	44.2	Vias are L1 > L3 >L1
	182.3		Total net delay
DRAM_CKE0_A	134.9	51.2	Vias are L1 > L3 > L1
	186.1		Total net delay
DRAM_CKE1_A	142.4	39.9	Vias are L1 > L3 > L1
	182.3		Total net delay

Table 23. LPDDR4 length matching example (byte lane 1 signals)

Net name	PCB delay (ps)	Pkg delay (ps)	Comments	
DRAM_SDQS1_T_A	84.2	48.6	Vias are L1 > L8 > L1	
	132.8		Total net delay	
DRAM_SDQS1_C_A	84.8	47.2	Vias are L1 > L8 > L1	
	132.0		Total net delay	
DRAM_DMI1_A	75.6	58.6	Routed on top layer, no via	

Table 23. LPDDR4 length matching example (byte lane 1 signals) (continued)

Net name	PCB delay (ps)	Pkg delay (ps)	Comments
	134.2		Total net delay
DRAM_DATA8_A	89.0	45.0	Routed on top layer, no via
	134.0		Total net delay
DRAM_DATA9_A	83.9	50.1	Routed on top layer, no via
	134.0		Total net delay
DRAM_DATA10_A	87.9	46.2	Routed on top layer, no via
	134.1		Total net delay
DRAM_DATA11_A	86.9	47.2	Routed on top layer, no via
	134.1		Total net delay
DRAM_DATA12_A	94.3	40.3	Routed on top layer, no via
	134.7		Total net delay
DRAM_DATA13_A	86	48.8	Routed on top layer, no via
	134.8		Total net delay
DRAM_DATA14_A	76.4	58.4	Routed on top layer, no via
	134.8		Total net delay
DRAM_DATA15_A	81.8	52.4	Routed on top layer, no via
	134.2		Total net delay

# 3.4.2.2 LPDDR4-3000 routing example (i.MX 8M Mini)

Figure 3, Figure 4, and Figure 5 show the placement and routing of the LPDDR4 signals on the i.MX 8M Mini EVK board. The CLK and DQS signals are routed on the bottom layer to save routing space on the top layer and layer 3. Channel A data byte lane 1 and channel B data byte lane 0 signals are routed on the top layer, and Channel A data byte lane 0, channel B data byte lane 1, and CA/CTL signals are routed on layer 3. This is to make the signal travel on the via as short as possible to minimize via crosstalk.

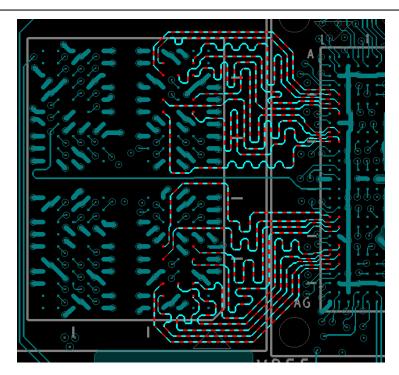


Figure 3. i.MX 8M Mini EVK board LPDDR4 routing (top layer)

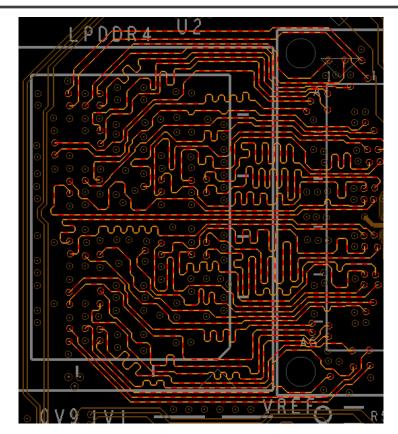


Figure 4. i.MX 8M Mini EVK board LPDDR4 routing (layer 3)

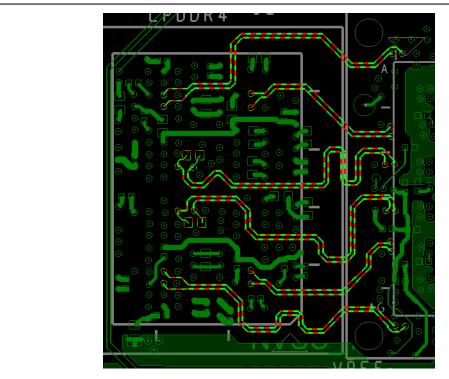


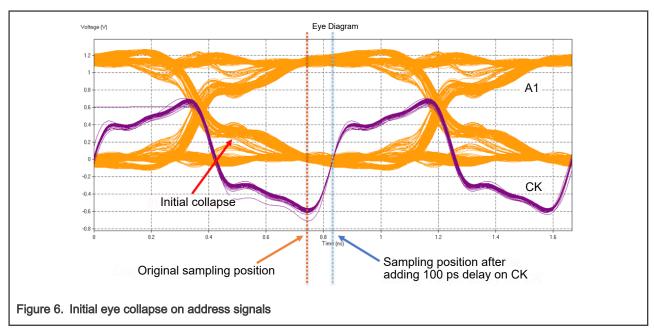
Figure 5. i.MX 8M Mini EVK board LPDDR4 routing (bottom layer)

#### 3.4.3 i.MX 8M Mini DDR4-2400 design recommendations

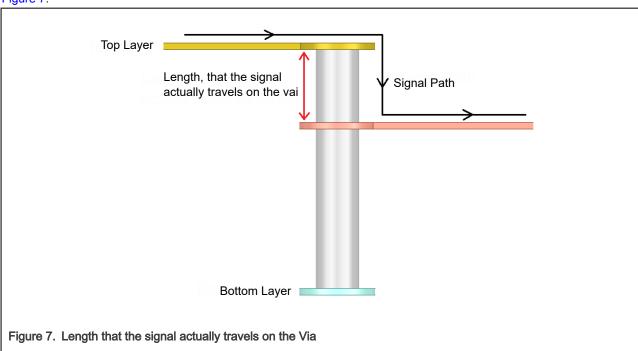
The following list provides some generic guidelines for implementing an i.MX 8M Mini design using DDR4.

- 1. It is expected that the layout engineer and the design team already have experience and training with DDR designs at speeds of 1.2 GHz / 2400 MT/s.
- 2. A 2 pcs x 16 DRAM routed in T-topology is recommended to achieving a total 2 GB density. When using T-topology routing, it is recommended keeping the propagation delay of each branch less than 150 ps (about 900 mils in length), with no larger than 10 ps difference between the two branches. In this case, VTT termination can be eliminated to ease routing and save BOM costs. In addition, there is an initial collapse on the eye diagram of Addr/Cmd/Ctrl due to the absence of VTT termination. To make the sampling position still at the center of the eye opening, CK should be routed with propagation delay 100 ps larger than that of Addr/Cmd/Ctrl, see Figure 6.

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- 1. DQ/DMI signal traces must refer to the solid GND plane only. Addr/Cmd/Ctrl signal traces can refer to GND plane only or GND+VDDQ plane (when routed as a strip line). Referring to the VDDQ plane only is not allowed.
- 2. Keep edge-to-edge spacing of high-speed signal traces no less than 1.5 times the trace width to minimize trace crosstalk.
- 3. At speed of 2400 MT/s, signal vias can be a significant source of crosstalk. If not properly designed, it can introduce crosstalk larger than that from the trace. To minimize via crosstalk, make sure that the number of vias on each point-to-point signal is no more than two. For T-topology signal, only one via at transmitter, one at T-junction, one at each receiver is allowed. Place at least one ground-stitching via within 50 mils of signal via when switching reference planes to provide a continuous return path and reduce crosstalk. If it is not possible to place enough ground-stitching vias due to space limitation, try to make the length that the signal actually travels on the via as short as possible, see Figure 7.



- 1. CLK and DQS signal can be routed on different layers with DQ/CA signals to ease routing. When doing this, keep not less than five times trace width spacing from other signals.
- 2. Use time delay instead of length when performing the delay matching. The delay matching includes the PCB trace delay and the IC package delay.
- 3. Incorporate the package pin delay into the CAD tool's constraint manager.
- 4. Include the delay of vias when performing delay matching. This can be realized in the Allegro tool by enabling the "Z-Axis Delay" in "Setup > Constraints > Modes".

NOTE	
Byte swapping between upper/lower byte lane is allowed. Bit swapping of Cmd/Addr/Ctrl s Byte swapping between upper/lower byte lane is allowed.	ignals is NOT allowed.

In general, the 2 pcs DDR4 DRAM should be placed 300 mils away from each other, with 150 mils from the i.MX 8M Mini.

5. Enable the Data Bus Inversion (DBI) feature. It can help reduce both power consumption and power noise.

#### 3.4.3.1 i.MX 8M Mini DDR4-2400 routing recommendations

DDR4-2400 must be routed with signal fly times matched shown in Table 24. The delay of the via transitions must be included in the overall calculation. This can be realized in the Allegro tool by enabling the "Z-Axis Delay" in "Setup > Constraints > Modes".

An example of the delay match calculation has been shown for the i.MX 8M Mini DDR4 EVK board design in Table 25 and Table 26. This analysis is done for the DDR4-2400 implementation using the i.MX 8M Mini. In Table 25 and Table 26, the "PCB delay" column is obtained directly from the Allegro PCB file, and the "Pkg delay" column is the package delay obtained from Table 31.

Table 24. i.MX 8M Mini DDR4-2400 routing recommendations

DDR4-2400				
DDR4/DDR3L signal	Group	PCB + package prop	PCB + package prop delay	
		Min.	Max.	
CK_t/CK_c	Clock	Short as possible	500 ps	Match the true/complement signals within 1 ps.
A[13:0]/BA[1:0]/BG0	Address/ Command/ Control	CK_t - 125 ps	CK_t - 75 ps	See section 3.4.3
CS/RAS/WE/CAS				more details.
CKE/ODT				
DQS0_t/DQS0_c	Byte 0 - DQS	Short as possible	CK_t + 1.0 * <sup>t</sup> CK	Match the true/complement
DM0	Byte 0 - Data	DQS0_t -10 ps	DQS0_t +10 ps	signals of DQS within 1 ps.
DQ[7:0]				within 1 ps.
DQS1_t/DQS1_c	Byte 1 - DQS	Short as possible	CK_t + 1.0 * <sup>t</sup> CK	
DM1	Byte 1 - Data	DQS1_t -10 ps	DQS1_t +10 ps	
DQ[15:8]				

Table continues on the next page...

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Table 24. i.MX 8M Mini DDR4-2400 routing recommendations (continued)

DDR4-2400				
DDR4/DDR3L signal	Group	PCB + package prop delay		Considerations
		Min.	Max.	
DQS2_t/DQS2_c	Byte 2 - DQS	Short as possible	CK_t + 1.0 * <sup>t</sup> CK	
DM2	Byte 2 - Data	DQS2_t -10 ps	DQS2_t +10 ps	
DQ[23:16]				
DQS3_t/DQS3_c	Byte 3 - DQS	Short as possible	CK_t + 1.0 * <sup>t</sup> CK	1
DM3	Byte 3 - Data	DQS3_t -10 ps	DQS3_t +10 ps	
DQ[31:24]				

Table 25. DDR4 delay matching example (Addr/Cmd/Ctrl/CK signals)

Net name	PCB delay (ps)	Pkg delay (ps)	Comment
DRAM_A0 U1.AD5:U2.P3	237.9	56.5	Vias are L1 > L6 > L8 > L1
	294.4	,	Total net delay
DRAM_A0 U1.AD5:U3.P3	239.3	56.5	Vias are L1 > L4 > L6 > L8
	295.8		Total net delay
DRAM_A1 U1.U1:U2.P7	248.4	42.2	Vias are L1 > L3 > L1
	290.6		Total net delay
DRAM_A1 U1.U1:U3.P7	248.7	42.2	Vias are L1 > L3 > L1
	290.9		Total net delay
DRAM_A2 U1.U2:U3.R3	249.3	41.8	Vias are L1 > L3 > L1
	291.2		Total net delay
DRAM_A2 U1.U2:U2.R3	249.3	41.8	Vias are L1 > L3 > L1
	291.2		Total net delay
DRAM_A3 U1.N6:U2.N7	269.1	22.4	Vias are L1 > L6 > L3 > L1
	291.5		Total net delay
DRAM_A3 U1.N6:U3.N7	268.6	22.4	Vias are L1 > L6 > L3 > L1

Table 25. DDR4 delay matching example (Addr/Cmd/Ctrl/CK signals) (continued)

Net name	PCB delay (ps)	Pkg delay (ps)	Comment
	291	,	Total net delay
DRAM_A4 U1.K5:U3.N3	248.5	43.1	Vias are L1 > L6 > L8 > L1
	291.6	,	Total net delay
DRAM_A4 U1.K5:U2.N3	247.6	43.1	Vias are L1 > L6 > L8 > L1
	290.7		Total net delay
DRAM_A5 U1.N5:U2.P8	265.7	32.0	Vias are L1 > L6 > L8 > L1
	297.7	,	Total net delay
DRAM_A5 U1.N5:U3.P8	265.8	32.0	Vias are L1 > L6 > L8 > L1
	297.8	,	Total net delay
DRAM_A6 U1.N4:U3.P2	258.7	33.8	Vias are L1 > L6 > L3 > L1
	292.5	,	Total net delay
DRAM_A6 U1.N4:U2.P2	258.5	33.8	Vias are L1 > L6 > L3 > L1
	292.4		Total net delay
DRAM_A7 U1.E4:U2.R8	237.1	54.8	Vias are L1 > L6 > L8 > L1
	291.9		Total net delay
DRAM_A7 U1.E4:U3.R8	238.2	54.8	Vias are L1 > L6 > L8 > L1
	293	1	Total net delay
DRAM_A8 U1.D5:U2.R2	238.1	59.7	Vias are L1 > L6 > L3> L1
	297.7	,	Total net delay
DRAM_A8 U1.D5:U3.R2	240.2	59.7	Vias are L1 > L6 > L3 > L1
	299.9		Total net delay
DRAM_A9 U1.J5:U2.R7	256.8	35.8	Vias are L1 > L6 > L8 > L1
	292.5	ı	Total net delay
DRAM_A9 U1.J5:U3.R7	257.5	35.8	Vias are L1 > L6 > L8 > L1
	293.3	,	Total net delay

Table 25. DDR4 delay matching example (Addr/Cmd/Ctrl/CK signals) (continued)

Net name	PCB delay (ps)	Pkg delay (ps)	Comment
DRAM_A10 U1.AC4:U2.M3	232.1	59.5	Vias are L1 > L6 > L3 > L1
	291.6	'	Total net delay
DRAM_A10 U1.AC4:U3.M3	231.1	59.5	Vias are L1 > L6 > L > L1
	290.6	,	Total net delay
DRAM_A11 U1.K6:U3.T2	263.8	29.1	Vias are L1 > L6 > L3 > L1
	292.9		Total net delay
DRAM_A11 U1.K6:U2.T2	263.9	29.1	Vias are L1 > L6 > L3 > L1
	293		Total net delay
DRAM_A12 U1.J6:U3.M7	251.3	39.6	Vias are L1 > L6 > L8 > L1
	290.9	,	Total net delay
DRAM_A12 U1.J6:U2.M7	251.2	39.6	Vias are L1 > L6 > L8 > L1
	290.8		Total net delay
DRAM_A13 U1.W6:U3.T8	262.2	31.9	Vias are L1 > L6 > L8 > L1
	294.1		Total net delay
DRAM_A13 U1.W6:U2.T8	263.2	31.9	Vias are L1 > L6 > L8 > L1
	295.1	,	Total net delay
DRAM_BA0 U1.V6:U2.N2	262.2	34.4	Vias are L1> L6 > L8 > L1
	296.6		Total net delay
DRAM_BA0 U1.V6:U3.N2	261.8	34.4	Vias are L1 > L6 > L8 > L1
	296.1		Total net delay
DRAM_BA1 U1.N1:U3.N8	237.3	53.4	Vias are L1 > L3 > L1
	290.7		Total net delay
DRAM_BA1 U1.N1:U2.N8	237.7	53.4	Vias are L1 > L3 > L1
	291.1	'	Total net delay
DRAM_BG0 U1.L2:U3.M2	251.4	41.1	Vias are L1 > L3 > L1

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Table 25. DDR4 delay matching example (Addr/Cmd/Ctrl/CK signals) (continued)

Net name	PCB delay (ps)	Pkg delay (ps)	Comment
	292.6		Total net delay
DRAM_BG0 U1.L2:U2.M2	249.8	41.1	Vias are L1 > L3 > L1
	290.9	'	Total net delay
DRAM_CK_C U1.M2:U2.K8	351.1	39.4	Vias are L1 > L8 > L1
	390.5		Total net delay
DRAM_CK_C U1.M2:U3.K8	357.2	39.4	Vias are L1 > L8 > L1
	396.5		Total net delay
DRAM_CK_T U1.M1:U3.K7	356.3	39.1	Vias are L1 > L8 > L1
	395.4		Total net delay
DRAM_CK_T U1.M1:U2.K7	351.3	39.1	Vias are L1 > L8 > L1
	390.5		Total net delay
DRAM_NACT U1.F6:U3.L3	246.8	45.7	Vias are L1 > L6 > L3 > L1
	292.5		Total net delay
DRAM_NACT U1.F6:U2.L3	247.8	45.7	Vias are L1 > L6 > L3 > L1
	293.5		Total net delay
DRAM_NALERT U1.R2:U3.P9	255.7	36.0	Vias are L1 > L3 > L1
	291.7		Total net delay
DRAM_NALERT U1.R2:U2.P9	255.2	36.0	Vias are L1 > L3 > L1
	291.2		Total net delay
DRAM_NCAS(A15)	260.3	38.6	Vias are L1 > L6 > L8 > L1
U1.R5:U3.M8	298.9		Total net delay
DRAM_NCAS(A15)	260.4	38.6	Vias are L1 > L6 > L8 > L1
U1.R5:U2.M8	299	'	Total net delay
DRAM_NCKE U1.F4:U2.K2	241.0	51.2	Vias are L1 > L6 > L3 > L1
	292.2		Total net delay

Table 25. DDR4 delay matching example (Addr/Cmd/Ctrl/CK signals) (continued)

Net name	PCB delay (ps)	Pkg delay (ps)	Comment
DRAM_NCKE U1.F4:U3.K2	242.2	51.2	Vias are L1 > L6 > L3 > L1
	293.4		Total net delay
DRAM_NCS U1.K4:U3.L7	257.0	35.9	Vias are L1 > L6 > L3 > L1
	292.9		Total net delay
DRAM_NCS U1.K4:U2.L7	255.9	35.9	Vias are L1 > L6 > L3 > L1
	291.8	'	Total net delay
DRAM_NRAS U1.T2:U3.L8	240.4	51.2	Vias are L1 > L3 > L1
	291.7		Total net delay
DRAM_NRAS U1.T2:U2.L8	240.9	51.2	Vias are L1 > L3 > L1
	292.1		Total net delay
DRAM_NRESET U1.R1:U3.P1	255.7	38.1	Vias are L1 > L3 > L1
	293.8		Total net delay
DRAM_NRESET U1.R1:U2.P1	252.4	38.1	Vias are L1 > L3 > L1
	290.5		Total net delay
DRAM_NWE(A14)	247.8	43.1	Vias are L1 > L3 > L1
U1.T1:U2.L2	290.9	'	Total net delay
DRAM_NWE(A14)	247.8	43.1	Vias are L1> L3 > L1
U1.T1:U3.L2	290.9	'	Total net delay
DRAM_ODT U1.V5:U3.K3	271.5	26.5	Vias are L1 > L6 > L3 > L1
	298		Total net delay
DRAM_ODT U1.V5:U2.K3	270.4	26.5	Vias are L1 > L6 > L3 > L1
	296.9		Total net delay
DRAM_PARITY U1.R6:U3.T3	264.9	29.0	Vias are L1 > L6 > L3 > L1
	293.9		Total net delay
DRAM_PARITY U1.R6:U2.T3	262.8	29.0	Vias are L1 > L6 > L3 > L1

Table 25. DDR4 delay matching example (Addr/Cmd/Ctrl/CK signals) (continued)

Net name	PCB delay (ps)	Pkg delay (ps)	Comment
	291.8		Total net delay

# Table 26. DDR4 delay matching example (Byte0 signals)

Net Name	PCB Delay (ps)	Pkg Delay (ps)	Comment
DRAM_DMI0	101.8	57.2	Vias are L1 > L3 > L1
	159.0		Total net delay
DRAM_DQS0_N	102.6	58.9	Vias are L1 > L8 > L1
	161.6		Total net delay
DRAM_DQS0_P	102.9	59.0	Vias are L1 > L8 > L1
	161.9		Total net delay
DRAM_DQ0	114.0	47.2	Vias are L1 > L3 > L1
	161.2		Total net delay
DRAM_DQ1	117.3	43.0	Vias are L1 > L3 > L1
	160.4		Total net delay
DRAM_DQ2	104.5	54.6	Vias are L1 > L3 > L1
	159.1		Total net delay
DRAM_DQ3	106.5	51.7	Vias are L1> L3> L1
	158.2		Total net delay
DRAM_DQ4	98.9	59.9	Vias are L1 > L3 > L1
	158.8		Total net delay
DRAM_DQ5	99.6	58.1	Vias are L1 > L3 > L1
	157.7		Total net delay
DRAM_DQ6	101.9	64.6	Vias are L1 > L3 > L1
	166.5		Total net delay
DRAM_DQ7	105.3	51.4	Vias are L1 > L3 > L1
	156.7		Total net delay

#### 3.4.3.2 DDR4-2400 routing example (i.MX 8M Mini)

Figure 8, Figure 9, Figure 10, and Figure 11 shows the placement and routing of the DDR4 signals on the i.MX8M Mini DDR4 EVK board.

The CK and DQS signals are routed on the bottom layer to save the routing space of other signal layers. Data signals are all routed on the top layer and layer 3, which can minimize via crosstalk to achieve enough timing margin for the 2400 MT/s high-speed signals. This is to make the signal travel on the via as short as possible to minimize via crosstalk. Addr/Cmd/Ctrl signals are routed in T-topology, with a trunk on the top layer and layer 6, and a branch on layer 3 and the bottom layer. Applying the same principle of making the length that the signal actually travels on the via short to minimize via crosstalk, for the trunks routed on the top layer, their branches are all routed on layer 3, forming a layer transition of L1 > L3 > L1, which means that no ground via is needed. And for the trunks routed on layer 6, their branches are mostly routed on layer 3, forming a layer transition of L1 > L6 > L3 > L1, so that ground vias are only needed under the 8M Mini package and at T-junction. The remaining branches are routed on the bottom layer, forming a layer transition of L1 > L6 > L8 > L1, which means ground vias are needed under the 8M Mini package as well as both DRAM packages.

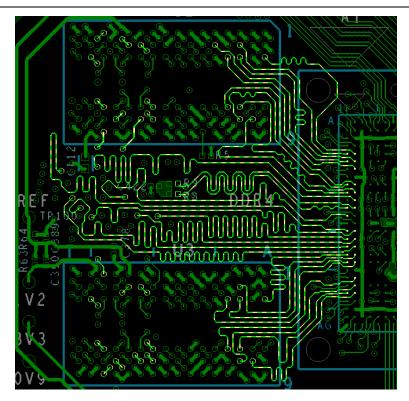


Figure 8. i.MX 8M Mini DDR4 EVK board DDR4 routing (top layer)

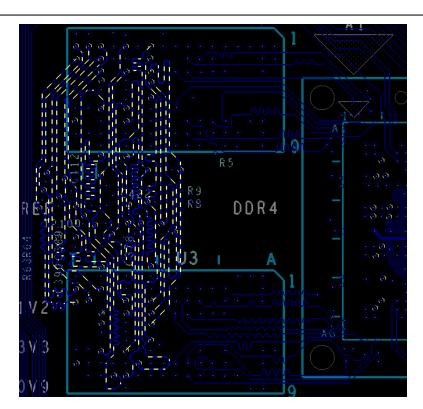


Figure 9. i.MX 8M Mini DDR4 EVK board DDR4 routing (layer 3)

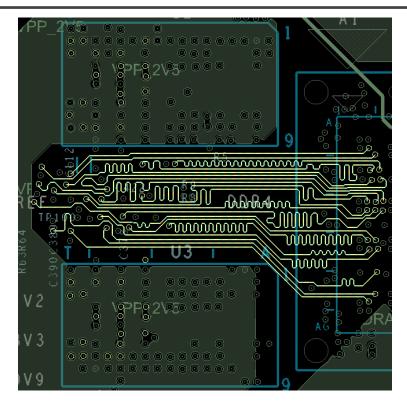
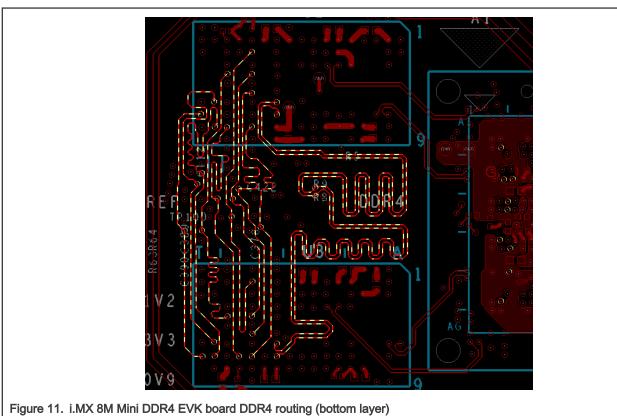


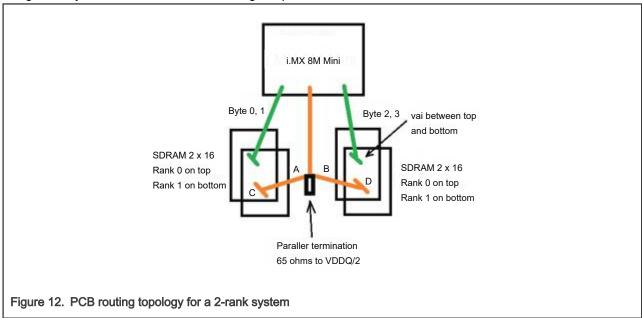
Figure 10. i.MX 8M Mini DDR4 EVK board DDR4 routing (layer 6)



#### 3.4.4 i.MX 8M Mini DDR3L-1600 design recommendations

The following list provides some generic guidelines for implementing an i.MX8M Mini design using DDR3L.

1. 4 pcs x16 DRAM routed in T-topology forming a 2-rank system is recommended to achieving a total 2 GB density. And it would be best to mount each rank of SDRAM on the top and bottom of the board mirroring each other in a clamshell design as they do for DIMM modules for the highest performance.



- For data bytes, route straight from SoC to the SDRAM devices and via up and down with minimal stubs, see Figure
   12. For address/command signals, it is a "T" structure with a branch to the SDRAM devices and via up and down with minimal stubs. And add a parallel termination (about 65 ohms to VDDQ/2 or VTT) at the branch point of the "T".
- The branch and stubs to the SDRAM pins must be the same length on both sides of the branch point (A+C=B+D); otherwise, the signal shows significant distortion. In addition, try to minimize the length of the branch as it is unterminated at the SDRAM devices.
- 4. All data signals within a byte lane should have the same number of vias/layer changes.
- 5. All the high-speed signal traces must be referred to as solid GND or NVCC\_DRAM (VDDQ) plane. Do not refer to other power planes.
- 6. For DQ nets, bit swapping within each slice/byte lane is allowed.
- 7. For address nets, use address mirroring to minimize top-to-bottom stubs. i.MX 8M Mini supports address mirroring but the wiring from i.MX 8M Mini to the two DRAM ranks must conform to Figure 1.

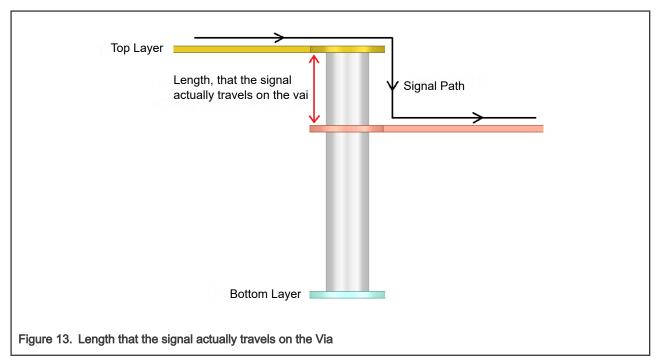
For detailed information about Address Mirroring Feature, see Section 3.1 in DDR3 SDRAM Unbuffered DIMM Design Specification.

Table 27. Wiring definition for DDR3L address mirroring

DDR3L-1600				
i.MX 8M Mini pin	DRAM pin			
	Rank 0	Rank 1		
A3	A3	A4		
A4	A4	A3		
A5	A5	A6		
A6	A6	A5		
A7	A7	A8		
A8	A8	A7		
BA0	BA0	BA1		
BA1	BA1	BA0		

- 8. The DQ/DMI/DQS signal must follow the "3 W" rule (center to center) to minimize trace crosstalk.
- 9. Place at least one ground-stitching via within 50 mils of the signal via when switching reference planes to provide a continuous return path and reduce crosstalk. If it is not possible to place enough ground-stitching vias due to space limitation, try to make the length that the signal actually travels on the via as short as possible, as shown in Figure 13.

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- 10. Use time delay instead of length when performing the delay matching. The delay matching includes the PCB trace delay and the IC package delays.
- 11. Incorporate the package pin delay into the CAD tool's constraint manager.
- 12. Consider the delay of vias when performing delay matching. This can be realized in the Allegro tool by enabling "Z-Axis Delay" in "Setup > Constraints > Modes".

#### 3.4.4.1 i.MX 8M Mini DDR3L-1600 routing recommendations

DDR3L-1600 must be routed with signal fly times and must match as listed in Table 28.

The delay of the via transitions must be included in the overall calculation. This can be realized in the Allegro tool by enabling "Z-Axis Delay" in "Setup > Constraints > Modes".

An example of the delay match calculation is listed for the i.MX 8M Mini validation board design in Table 29 and Table 30. This analysis is done for the DDR3L-1600 implementation using the i.MX 8M Mini. In Table 29, the "PCB delay" column is obtained directly from the Allegro PCB file, and the "Pkg delay" column is the package delay obtained from Table 31.

NXP recommends that users simulate their DDR implementation before fabricating PCBs.

Table 28. i.MX 8M Mini DDR3L-1600 routing recommendations

DDR3L-1600				
DDR4/DDR3L signal	Group	roup PCB + package prop delay		
		Min	Max	
CK_t/CK_c	Clock	Short as possible	500 ps	Match the true/complement signals within 1 ps.
A[15:0]	Address/ Command/ Control	CK_t - 25 ps	CK_t + 25 ps	-

Table continues on the next page...

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Table 28. i.MX 8M Mini DDR3L-1600 routing recommendations (continued)

DDR3L-1600				
DDR4/DDR3L signal	Group	PCB + package prop delay		Considerations
		Min	Max	
CS[1:0]/RAS/WE/CAS BA[2:0]				
CKE[1:0]/ ODT[1:0]				
DQS0_t/DQS0_c	Byte 0 - DQS	Short as possible	CK_t + 1.0 * <sup>t</sup> CK	Match the
DM0	Byte 0 - Data	DQS0_t -10 ps	DQS0_t +10 ps	true/complement signals of DQS
DQ[7:0]				within 1 ps.
DQS1_t/DQS1_c	Byte 1 - DQS	Short as possible	CK_t + 1.0 * <sup>t</sup> CK	
DM1	Byte 1 - Data	DQS1_t -10 ps	DQS1_t +10 ps	
DQ[15:8]				
DQS2_t/DQS2_c	Byte 2 - DQS	Short as possible	CK_t + 1.0 * <sup>t</sup> CK	
DM2	Byte 2 - Data	DQS2_t -10 ps	DQS2_t +10 ps	
DQ[23:16]				
DQS3_t/DQS3_c	Byte 3 - DQS	Short as possible	CK_t + 1.0 * <sup>t</sup> CK	
DM3	Byte 3 - Data	DQS3_t -10 ps	DQS3_t +10 ps	
DQ[31:24]				

Table 29. DDR3L delay matching example (CA/CTL/CMD/CK signals)

Net name	PCB delay (ps)	Pkg delay (ps)	Comment
A0	307.9	56.5	Vias are L1 > L4 > L3 > L1
U101.AD5:U102.N3	364.4		Total Net Delay
A1	308.6	42.2	Vias are L1 > L8 > L6 > L1
U101.U1:U102.P7	350.8		Total Net Delay
A2	306	41.8	Vias are L1 > L8 > L3 > L1
U101.U2:U102.P3	347.8		Total Net Delay

Table 29. DDR3L delay matching example (CA/CTL/CMD/CK signals) (continued)

Net name	PCB delay (ps)	Pkg delay (ps)	Comment
A3	326.4	22.4	Vias are L1 > L4 > L3 > L1
U101.N6:U102.N2	348.8	1	Total Net Delay
A4	304.6	43.1	Vias are L1 > L4 > L6 > L1
U101.K5:U102.P8	347.7	1	Total Net Delay
A5	315.6	32.0	Vias are L1 > L4 > L3 > L1
U101.N5:U102.P2	347.6	1	Total Net Delay
A6	316.4	33.8	Vias are L1 > L8 > L6 > L1
U101.N4:U102.R8	350.2		Total Net Delay
A7	295.5	54.8	Vias are L1 > L4 > L3 > L1
U101.E4:U102.R2	350.3		Total Net Delay
A8	304.8	59.7	Vias are L1 > L4 > L6 > L1
U101.D5:U102.T8	364.5		Total Net Delay
A9	311.2	35.8	Vias are L1 > L4 > L6 > L1
U101.J5:U102.R3	347		Total Net Delay
A10	290.5	59.5	Vias are L1 > L4 > L6 > L1
U101.AC4:U102.L7	350		Total Net Delay
A11	318.1	29.1	Vias are L1 > L4 > L3 > L1
U101.K6:U102.R7	347.2		Total Net Delay
A12	307.1	39.6	Vias are L1 > L4 > L6 > L1
U101.J6:U102.N7	346.7		Total Net Delay
A13	329.9	31.9	Vias are L1 > L4 > L6 > L1
U101.W6:U102.T3	361.8		Total Net Delay
A14	308.9	41.2	Vias are L1 > L8 > L3 > L1
U101.L1:U102.T7	350.1		Total Net Delay
A15 U101.F6:U102.M7	302.8	45.7	Vias are L1 > L4 > L3 > L1

Table 29. DDR3L delay matching example (CA/CTL/CMD/CK signals) (continued)

Net name	PCB delay (ps)	Pkg delay (ps)	Comment
	348.5	,	Total Net Delay
BA0	314.6	34.4	Vias are L1 > L4 > L3 > L1
U101.V6:U102.M2	349	,	Total Net Delay
BA1	295.8	53.4	Vias are L1 > L8 > L6 > L1
U101.N1:U102.N8	349.2	,	Total Net Delay
BA2	310.7	41.1	Vias are L1 > L8 > L3 > L1
U101.L2:U102.M3	351.8	,	Total Net Delay
CAS_N	307	38.6	Vias are L1 > L4 > L3 > L1
U101.R5:U102.K3	345.6	,	Total Net Delay
CKE0	294.6	51.2	Vias are L1 > L8 > L6 > L1
U101.F4:U102.K9	345.8	,	Total Net Delay
CKE1	306.7	39.9	Vias are L1 > L4 > L3 > L8
U101.F5:U104.K	346.6	,	Total Net Delay
CLK0_C	316.2	39.4	Vias are L1 > L6 > L1
U101.M2:U102.K7	355.6		Total Net Delay
CLK0_T	316.2	39.1	Vias are L1 > L6 > L1
U101.M1:U102.J7	355.3		Total Net Delay
CLK1_C	303.9	51.6	Vias are L1 > L6 > L3 > L8
U101.AB5:U104.K7	355.5		Total Net Delay
CLK1_T	303.2	51.6	Vias are L1 > L6 > L3 > L8
U101.AB4:U104.J7	354.8	l	Total Net Delay
CS0_N	309.8	35.9	Vias are L1 > L4 > L3 > L1
U101.K4:U102.L2	345.7		Total Net Delay
CS1_N	306.2	42.1	Vias are L1 > L4 > L6 > L8
U101.AB6:U104.L2	348.3		Total Net Delay

Table 29. DDR3L delay matching example (CA/CTL/CMD/CK signals) (continued)

Net name	PCB delay (ps)	Pkg delay (ps)	Comment
ODT0	320.8	26.5	Vias are L1 > L4 > L6 > L1
U101.V5:U102.K1	347.3		Total Net Delay
ODT1	311.7	35.1	Vias are L1 > L4 > L3 > L8
U101.W5:U104.K1	346.8		Total Net Delay
RAS_N	303.4	51.2	Vias are L1 > L8 > L6 > L1
U101.T2:U102.J3	.354.6		Total Net Delay
WE_N U101.T1:U102.L3	304.2	43.1	Vias are L1 > L4 > L6 > L1
	347.3		Total Net Delay

Table 30. DDR3L delay matching example (CA/CTL/CMD/CK signals)

Net Name	PCB delay (ps)	Pkg delay (ps)	Comment
DM0	149.2	57.2	Vias are L1 > L3 > L1
	206.4		Total Net Delay
DQS0_C	149.7	58.9	Vias are L1 > L3 > L1
	208.6		Total Net Delay
DQS0_T	149.9	59	Vias are L1 > L3 > L1
	208.9		Total Net Delay
DQ0	157.5	47.2	Vias are L1 > L3 > L1
	204.7		Total Net Delay
DQ1	162.9	43	Vias are L1 > L3 > L1
	205.9		Total Net Delay
DQ2	150.4	54.6	Vias are L1 > L3 > L1
	205	,	Total Net Delay
DQ3	153	51.7	Vias are L1 > L3 > L1
	204.7		Total Net Delay
DQ4	149.6	59.9	Vias are L1 > L3 > L1

Table 30. DDR3L delay matching example (CA/CTL/CMD/CK signals) (continued)

Net Name	PCB delay (ps)	Pkg delay (ps)	Comment
	209.5		Total Net Delay
DQ5	152.6	58.1	Vias are L1 > L3 > L1
	210.7		Total Net Delay
DQ6	148.1	64.6	Vias are L1 > L3 > L1
	212.7		Total Net Delay
DQ7	158.9 51.4		Vias are L1 > L3 > L1
	210.3		Total Net Delay

#### 3.4.4.2 DDR3L-1600 Routing example (i.MX 8M Mini)

Figure 14, Figure 15, Figure 16, Figure 17, and Figure 18 show the placement and routing of the DDR3L signals on the i.MX 8M Mini validation board.

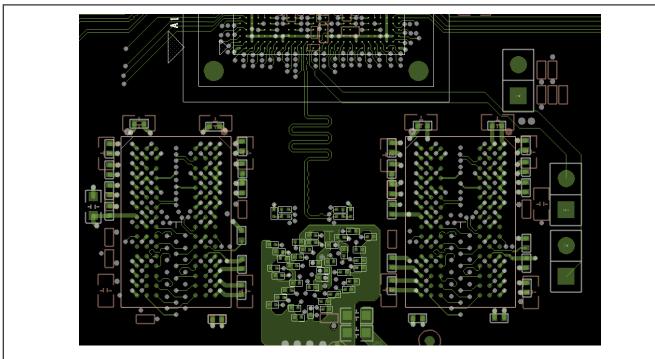


Figure 14. i.MX 8M Mini validation board DDR3L routing (top layer)

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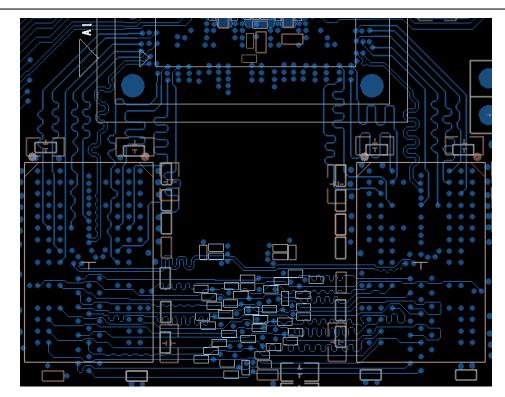


Figure 15. i.MX 8M Mini validation board DDR3L routing (layer 3)

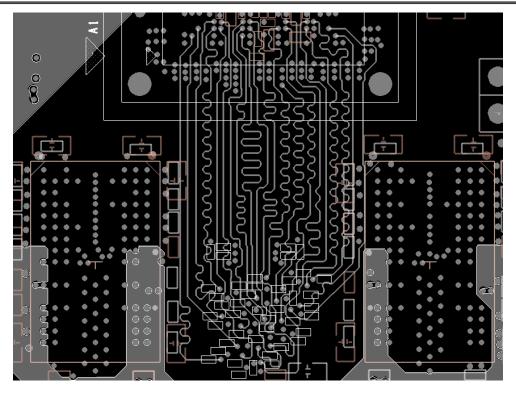


Figure 16. i.MX 8M Mini validation board DDR3L routing (layer 4)

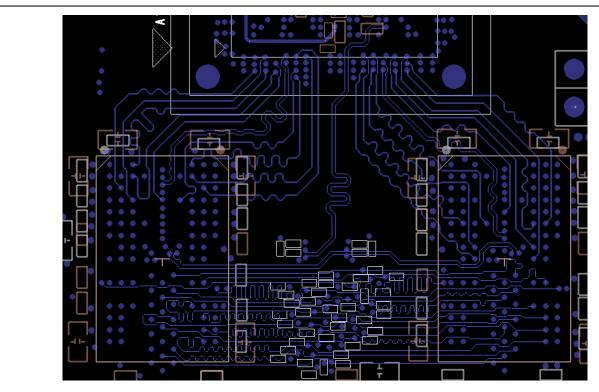


Figure 17. i.MX 8M Mini validation board DDR3L routing (layer 6)

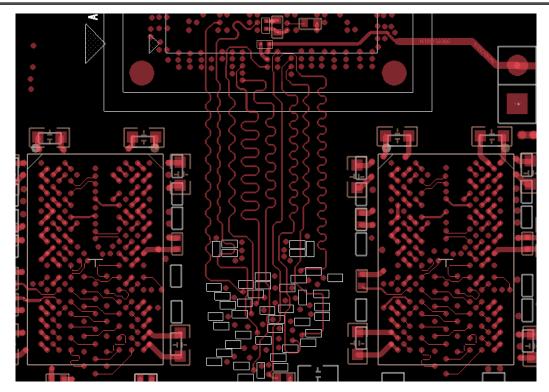


Figure 18. i.MX 8M Mini validation board DDR3L routing (Layer 8)

#### 3.4.5 i.MX 8M Mini DDR SI simulation guide

The simulation architecture includes the DDR controller (for example, the i.MX 8M Mini processor), the PCB and the DRAM device. The IBIS model for the i.MX 8M Mini processor is available from NXP. The DRAM device IBIS model must be obtained from the memory vendor.

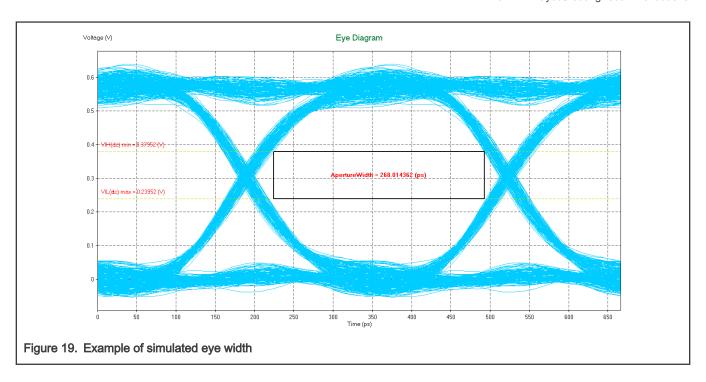
This section describes how to check SI performance of the layout for a DDR design using the i.MX 8M Mini.

- 1. Perform S-parameter extraction:
  - a. It requires a 2.5 D full-wave extraction tool, such as PowerSI from the Cadence.
  - b. Set the extraction bandwidth to 20 GHz.
  - c. Port reference impedance to 50 ohms for signal ports, and 0.1 ohm for power ports.
  - d. Coupled mode; Set the risetime to 20 ps and coupling coefficient to 1 %.
- 2. Perform time domain simulation:
  - a. Stimulus pattern: 500-bit random code and different pattern for each signal within the same byte.
  - b. Ideal power.
  - c. Probe at the die.
  - d. Simulation at slow corner (worst case).
  - e. Eye waveform triggered by aligning with the timing reference (DQS/CLK).

When the simulation is done, find the simulated worst eye width and compare with following requirements to see if it can pass:

- For LPDDR4-3000:
  - 1. DQ Write: Eye width @V<sub>REF</sub> ±70 mV should be over 248 ps.
  - 2. DQ Read: Eye width @V<sub>REF</sub> ±70 mV should be over 201 ps.
  - 3. Cmd/Addr/Ctrl: Eye width @V<sub>REF</sub> ±77.5 mV should be over 563 ps.
- For DDR4-2400:
  - 1. DQ Write: Eye width @V<sub>RFF</sub> ±65 mV should be over 276 ps.
  - 2. DQ Read: Eye width @V<sub>REF</sub> ±70 mV should be over 225 ps.
  - 3. Cmd/Addr/Ctrl: Eye width at threshold should be over 579 ps.
- For DDR3L-1600:
  - 1. DQ Write: Eye width at threshold should be over 395 ps.
  - 2. DQ Read: Eye width @641.5 ±70 mV should be over 370 ps.
  - 3. Cmd/Addr/Ctrl: Eye width at threshold should be over 727 ps.

For an example of simulated eye width of LPDDR4-3000 DQ write, see Figure 19.



#### 3.4.6 i.MX 8M Mini DDR package delay

The bond wires within the i.MX 8M Mini package must be accounted for and must be included in the match calculation while performing the required delay matching for LPDDR4/DDR4 routing,. Table 31 lists the propagation/fly time from the die I/O to the package ball.

Table 31. i.MX 8M Mini DDR package trace delays

Ball Name	Delay (ps)	Ball name	Delay (ps)
DRAM_AC00	51.2	DRAM_DM2	52.8
DRAM_AC01	39.9	DRAM_DM3	53.1
DRAM_AC02	35.9	DRAM_DQS0_N	58.9
DRAM_AC03	44.2	DRAM_DQS0_P	59.0
DRAM_AC04	41.1	DRAM_DQS1_N	47.2
DRAM_AC05	41.2	DRAM_DQS1_P	48.6
DRAM_AC06	45.7	DRAM_DQS2_N	48.6
DRAM_AC07	35.8	DRAM_DQS2_P	49.9
DRAM_AC08	39.6	DRAM_DQS3_N	55.0
DRAM_AC09	29.1	DRAM_DQS3_P	55.5
DRAM_AC10	54.8	DRAM_DQ00	47.2

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Table 31. i.MX 8M Mini DDR package trace delays (continued)

Ball Name Delay (ps) Ball name Delay (ps)				
Delay (ps)	Ball name	Delay (ps)		
59.7	DRAM_DQ01	43.0		
33.8	DRAM_DQ02	54.6		
32.0	DRAM_DQ03	51.7		
43.1	DRAM_DQ04	59.9		
22.4	DRAM_DQ05	58.1		
39.1	DRAM_DQ06	64.6		
39.4	DRAM_DQ07	51.4		
43.4	DRAM_DQ08	45.0		
51.6	DRAM_DQ09	50.1		
51.6	DRAM_DQ10	46.2		
47.7	DRAM_DQ11	47.2		
40.0	DRAM_DQ12	40.3		
41.8	DRAM_DQ13	48.8		
42.2	DRAM_DQ14	58.4		
53.4	DRAM_DQ15	52.4		
29.0	DRAM_DQ16	51.4		
31.9	DRAM_DQ17	49.9		
34.4	DRAM_DQ18	54.5		
59.5	DRAM_DQ19	42.0		
56.5	DRAM_DQ20	53.6		
34.3	DRAM_DQ21	49.8		
38.6	DRAM_DQ22	54.7		
43.1	DRAM_DQ23	48.0		
51.2	DRAM_DQ24	60.2		
26.5	DRAM_DQ25	51.3		
	59.7         33.8         32.0         43.1         22.4         39.1         39.4         43.4         51.6         47.7         40.0         41.8         42.2         53.4         29.0         31.9         34.4         59.5         56.5         34.3         38.6         43.1         51.2	59.7 DRAM_DQ01  33.8 DRAM_DQ02  32.0 DRAM_DQ03  43.1 DRAM_DQ04  22.4 DRAM_DQ05  39.1 DRAM_DQ06  39.4 DRAM_DQ07  43.4 DRAM_DQ08  51.6 DRAM_DQ09  51.6 DRAM_DQ10  47.7 DRAM_DQ10  41.8 DRAM_DQ12  41.8 DRAM_DQ13  42.2 DRAM_DQ14  53.4 DRAM_DQ15  59.0 DRAM_DQ16  31.9 DRAM_DQ16  31.9 DRAM_DQ16  31.9 DRAM_DQ17  34.4 DRAM_DQ18  59.5 DRAM_DQ19  56.5 DRAM_DQ20  34.3 DRAM_DQ21  38.6 DRAM_DQ22  43.1 DRAM_DQ24		

Table 31. i.MX 8M Mini DDR package trace delays (continued)

Ball Name	Delay (ps)	Ball name	Delay (ps)
DRAM_AC37	35.1	DRAM_DQ26	48.8
DRAM_AC38	42.1	DRAM_DQ27	58.0
DRAM_ALERT_N	36.0	DRAM_DQ28	59.1
DRAM_RESET_N	38.1	DRAM_DQ29	58.1
DRAM_DM0	57.2	DRAM_DQ30	50.0
DRAM_DM1	58.6	DRAM_DQ31	44.2

#### 3.4.7 High-speed routing recommendations

This section lists the routing traces for high-speed signals. For more information about general high-speed routing considerations, see High Frequency Design Considerations (document AN12298). The propagation delay and the impedance control should match to ensure the correct communication with the devices.

- · High-speed signals (DDR, PCIe, RGMII, MIPI, and so on) must not cross gaps in the reference plane.
- Avoid creating slots, voids, and splits into reference planes. Review via placements to ensure that they do not inadvertently create splits/voids (for example, space vias out to eliminate this possibility).
- Ensure that ground-stitching vias are present within 50 mils from signal layer transition vias on high-speed signals when transitioning between different reference ground planes.
- A solid GND plane must be directly under crystals, associated with components and traces.
- · Clocks or strobes that are on the same layer need at least 2.5x height from reference plane spacing from adjacent traces to reduce crosstalk.
- All synchronous interfaces should have appropriate bus delay matching.
- The true and complementary signal of a differential pair must have delay matched to within 1 ps.

#### 3.4.8 Reset architecture/routing

A reset button may be connected to PMIC\_RST\_B pin of the PMIC (PCA9450AAHN) for development purposes. This allows all voltages to be put to their initial default power-on state when depressing the reset button.

Pressing the reset button causes the PMIC to trigger a cold reset event. This causes all the power supplies except for the SNVS domain to be OFF. During this time, the POR B driven by the PMIC keeps asserting (low). This state keeps hundreds of milliseconds to provide enough time for the power supplies to be powered down, and then the power supplies start to ramp up again in the defined sequence. When all the power supplies have reached their operating voltages, POR\_B gets de-asserted, and the CPU may begin booting from reset.

#### 3.5 Trace impedance recommendations

Refer to Table 32 while creating or updating constraints in the PCB design tool to set up the impedances/trace widths.

Table 32. Trace impedance recommendations

Signal group	Impedance	PCB manufacturer tolerance (+/-)
All single-ended signals, unless specified	50 ohms Single-ended	10 %
DDR DQS/CLK, PCIe TX/RX data pairs, and reference clock	85 ohms Differential	10 %
USB differential signals	90 ohms Differential	10 %
Differential signals, including Ethernet, MIPI (CSI and DSI)	100 ohms Differential	10 %

#### 3.6 Power connectivity/routing

Delivering clean, reliable power to the i.MX 8M Mini internal power rails are critical to a successful board design. The PCB PDN should be designed to accommodate the maximum output current from each SMPS into the i.MX 8M Mini supply balls. Table 33 lists the design goals for each high-current i.MX 8M Mini power rail.

Table 33. i.MX 8M Mini maximum current design levels

Supply input	i.MX 8M Mini Max current (mA)
VDD_ARM	2200
VDD_SOC	1000
VDD_DRAM, VPU, GPU	2500
NVCC_DRAM	1000

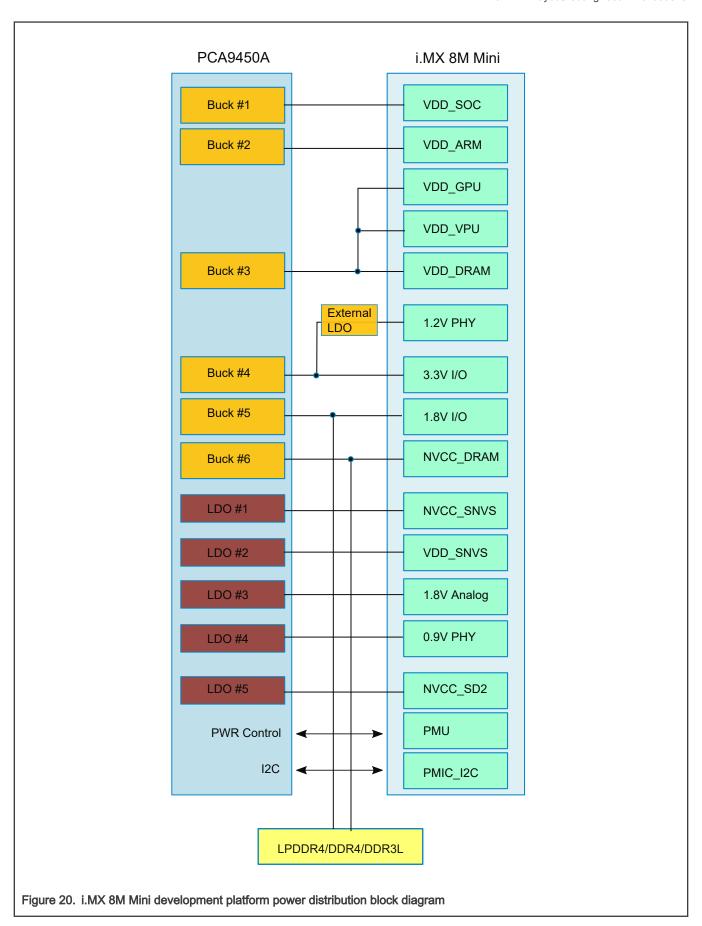
#### 3.6.1 i.MX 8M Mini power distribution block diagram

There are companion PMICs that provide a low-cost and efficient solution for powering the i.MX 8M Mini processor, for example, PCA9450AAHN.

PCA9450AAHN is a single chip Power Management IC (PMIC) designed to support i.MX 8MM family processor. It provides six buck converters, five LDOs, one 400 mA load switch, 2-channel level translator, and 32.768 kHz crystal oscillator driver.

The default output of BUCK6 is 1.1 V, which is for LPDDR4 NVCC\_DRAM. You can modify the voltage to 1.2 V for DDR4, and 1.35 V for DDR3L by programming PMIC in SPL code before the U-Boot or kernel image is loaded onto DDR. This function has been fully verified, so you can use the ONE PMIC part for all kinds of DDR memories.

i.MX 8M Mini power distribution block diagram shows a block diagram of the power tree of the NXP i.MX 8M Mini EVK board.



#### 3.6.2 Power routing/distribution requirements

The design for a good Power Delivery Network (PDN) is complicated. It includes:

- 1. Choose a good PCB stack-up (adequate Cu thicknesses, and layer assignments/utilization).
- 2. Optimize the placement and routing of the PDN. This includes good placement of the decoupling capacitors and connecting them to the power ground planes with as short and wide a trace as possible (as the increased inductance of a longer etch degrades the effectivity of the capacitor). Use the number/placement of capacitors on the NXP development platforms.
- 3. Optimize DC IR drop. This involves using very wide traces/plane fills to route high-current power nets and ensure an adequate number of vias on power net layer transitions. Neck down of fill areas should be minimized and current density minimized. The maximum DC IR drop on a board should be 2 % (preferably 1 %) of the voltage rail (for example, on a 1.1 V rail, the maximum voltage drop should be less than 0.022 V, preferably less than 0.011 V). See Table 34 for the DC IR drop requirement.
- 4. AC impedance check the target impedance at different frequencies should be below specified values. See Table 35 for the impedance targets vs. frequency for specified power rail for the i.MX 8M Mini PCB design.

Table 34. i.MX 8M Mini DC IR drop requirements

Supply input	Nominal voltage (V)	Max current (mA)	IR drop target	Corresponding power path resistance requirement (milliohms)
VDD_ARM	0.85/0.95/1.0	2200	< 2 %	< 7.7
VDD_SOC	0.85	1000	< 2 %	< 17
VDD_DRAM, VPU, and GPU	0.975	2500	< 2 %	< 7.8
NVCC_DRAM	1.1	1000	< 2 %	< 22

Table 35. i.MX 8M Mini PDN target impedance

Supply Input	< 20 MHz (milliohms)	20 - 100 MHz (milliohms)
VDD_ARM	36	170
VDD_SOC	24	117
VDD_DRAM, VPU, and GPU	24	110
NVCC_DRAM	15	70

#### 3.7 USB connectivity

The i.MX 8M Mini provides two complete USB2.0 interfaces and the following configurations (or any subset) are supported:

- Dedicated host or device using Type-A connector or Type-B connector.
- · Dual role using Type-C connector.

To implement a USB Type-C interface (UFP, DFP, or DRP) external hardware must be added to manage the two configuration channel IOs (CC1 and CC2) as well as monitor the plug orientation.

See the NXP development platform schematic for an example USB Type-C implementation.

#### 3.8 PCIe connectivity

The i.MX 8M Mini has one PCIe interface. There is a pair of pins with the name of PCIE\_CLK\_P/N. These pins are bidirectional which can either be used to feed 100 MHz reference clock to the PHY from an external clock source, or to output an internally generated 100 MHz reference clock to PCIe connector or PCIe device.

On EVK, a PCIe clock generator chip (9FGV0241) is used to feed a high-quality clock to both the PHY and connecter/device. If a PCIe clock generator is not available, use the internal clock of the chip.

NOTE

The internal clock exhibits larger jitter than that from PCIe clock generator.

#### 3.9 Unused input/output terminations

#### 3.9.1 i.MX 8M Mini unused input/output guidance

For the i.MX 8M Mini, the I/Os and power rails of an unused function can be terminated to reduce overall board power. Table 36 lists the connectivity examples for unused power supply rails and Table 37 lists the connectivity examples for unused signal contacts/interfaces.

Table 36. i.MX 8M Mini unused power rail strapping recommendations

Function	Ball name	Recommendation if unused
MIPI-CSI and MIPI-DSI	VDD_MIPI_1P8, VDD_MIPI_1P2, VDD_MIPI_0P9	Leave unconnected <sup>1</sup>
PCle	VDD_PCI_1P8, VDD_PCI_0P8	Leave unconnected
USB	VDD_USB_3P3, VDD_USB_1P8, VDD_USB_0P8	Leave unconnected <sup>2</sup>
VPU	VDD_VPU	Leave unconnected
GPU	VDD_GPU	Leave unconnected
Digital I/O supplies	NVCC_CLK, NVCC_ECSPI, NVDD_ENET, NVCC_GPIO1, NVCC_I2C, NVCC_JTAG, NVCC_NAND, NVCC_SAI1, NVCC_SAI2, NVCC_SAI3, NVCC_SAI5, NVCC_SD1, NVCC_SD2, NVCC_UART, NVCC_SNVS_1P8, PVCC0_1P8, PVCC1_1P8, PVCC2_1P8	All digital I/O supplies listed in this table must be powered under normal conditions whether the associated I/O pins are in use or not, and associated I/O pins must enable pull in pad control register to limit any floating gate current.

- 1. These balls supply both MIPI-CSI and MIPI-DSI interfaces and must be connected/powered if either is used.
- 2. These balls supply all the USB interfaces (USB1, USB2) and must be connected/powered if any USB port is used.

Table 37. i.MX 8M Mini unused signal strapping recommendations

Function	Ball name	Recommendation if unused
MIPI-CSI	MIPI_CSI_CLK_P/N, MIPI_CSI_Dx_P/N	Tie all signals to ground
MIPI-DSI	MIPI_DSI_CLK_P/N, MIPI_DSI_Dx_P/N, MIPI_VREG_CAP	Leave unconnected
PCIe	PCIE_TXN_P/N, PCIE_RXN_P/N, PCIE_CLK_P/N, PCIE_RESREF	Leave unconnected

Table continues on the next page...

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#### Table 37. i.MX 8M Mini unused signal strapping recommendations (continued)

Function	Ball name	Recommendation if unused
USB1	USB1_VBUS, USB1_DN/DP, USB1_ID, USB1_TXRTUNE	Leave unconnected
USB2	USB2_VBUS, USB2_DN/DP, USB2_ID, USB2_TXRTUNE	Leave unconnected

## Chapter 4 Avoiding board bring-up problems

#### 4.1 Introduction

This chapter describes how to avoid mistakes when bringing up a board for the first time. The recommendations below consist of basic techniques for detecting board issues and preventing/locating the three issues encountered: power, clocks, and reset.

#### 4.2 Avoiding power pitfalls-current

Excessive current can damage the board. Use a current-limiting laboratory supply set to the expected main current draw (at most). Monitor the main supply current with an ammeter when powering up the board for the first time. You can use the supply's internal ammeter if it is available. By monitoring the main supply current and controlling the current limit, any excessive current can be detected before permanent damage occurs.

Before the board test, you must ohm-out the board power rails to the ground to verify that there are no short circuits. So that you can power on the board without damaging the board and/or components.

#### 4.3 Avoiding power pitfalls-voltage

To avoid incorrect voltage rails, create a basic table called a sample voltage report, see Table 38, prior to board bring up/testing. Table 38 helps to validate all the supplies if reaching to the expected level.

To create a voltage report, list the following:

- · Board voltage sources.
- Default power-up values for the board voltage sources.
- · Best location on the board to measure the voltage level of each supply.

Determine the best measurement location for each power supply to avoid a large voltage drop (IR drop) on the board. The drop causes inaccurate voltage values. The following steps help to measure the voltage accurately:

- 1. Measure closest to the load for the i.MX 8M Mini processor).
- 2. Make two measurements: The First after initial board power-up and the second while running a heavy use case that stresses the i.MX 8M Mini processor.

Ensure that the i.MX 8M Mini power supply meets the DC electrical specifications as listed in the chip-specific data sheet. See Table 38 for a sample voltage report table.

NOTE
The report in Table 38 is for i.MX 8M Mini EVK board. Sample voltage reports for customer PCBs are different
from this, depending on the Processor and Power Management IC (PMIC) used and the assignment of the PMIC
power resources.

Table 38. Sample voltage report table

Source	Net name	Expected (V)	Measured (V)	Measure point	Comment
DC jack input	VSYS	5	-	TP51	Main supply for board
PCA9450A_BUCK1	VDD_SOC_0V8	0.85 <sup>1</sup>	-	TP22	-

Table continues on the next page...

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Table 38. Sample voltage report table (continued)

Source	Net name	Expected (V)	Measured (V)	Measure point	Comment
PCA9450A_BUCK2	VDD_ARM_0V9	0.85/0.95/1.02	-	TP23	-
PCA9450A_BUCK3	VDD_DRAM and PU_0V9	0.85/0.90/0.95 <sup>3</sup>	-	TP24	-
PCA9450A_BUCK4	VDD_3V3/NVCC_3V3	3.3	-	TP25	-
PCA9450A_BUCK5	VDD_1V8/NVCC_1V8	1.8	-	TP26	-
PCA9450A_BUCK6	NVCC_DRAM_1V1	1.1/1.2/1.35 <sup>4</sup>	-	TP27	-
PCA9450A_LDO1	NVCC_SNVS_1V8	1.8	-	TP28	-
PCA9450A_LDO2	VDD_SNVS_0V8	0.8 <sup>5</sup>	-	TP29	-
PCA9450A_LDO3	VDDA_1V8	1.8	-	TP32	-
PCA9450A_LDO4	VDD_PHY_0V9	0.9	-	TP30	-
Extra LDO	VDD_PHY_1V2	1.2	-	TP31	-
PCA9450A_LDO5	NVCC_SD2	3.3/1.8	-	TP33	Can be either under SW control

- 1. The default output voltage of PCA9450A BUCK1 is 0.85 V. If PCIe is unused, the software can alternatively configure BUCK1 to 0.82 V in SPL before DDR initialization.
- 2. The default output voltage of PCA9450A of BUCK2 is 0.85 V for 1.2 GHz operation. The software changes it to 0.95 V for 1.6 GHz, 1.0 V for 1.8 GHz.
- 3. The default output voltage of PCA9450A\_BUCK3 is 0.85 V. Software changes it to the required value in SPL before DDR initialization. Refer to IMX8MMCEC/IMX8MMIEC for more detailed information.
- 4. 1.1 V for LPDDR4, 1.2 V for DDR4, 1.35 V for DDR3L, PCA9450A\_BUCK6 default output voltage is 1.1 V. Software changes it to the required value in SPL before DDR initialization.
- 5. The default output voltage of PCA9450A LDO2 is 0.85 V. Software changes it to the required value in SPL before DDR initialization.

#### 4.4 Checking for clock pitfalls

Problems with the external clocks are another board bring-up issue. Ensure that all the clock sources are running as expected.

The 24M\_XTALI/24M\_XTALO, and the RTC clocks are the main clock sources for 24 MHz and 32.768 kHz reference clocks. Although not required, the use of low jitter external oscillators to feed CLK1\_P/N can be an advantage if low jitter or special frequency clock sources are required by modules driven by CLKIN\_1/2. See the CCM chapter in the i.MX 8M Mini chip reference manual for details.

When checking crystal frequencies, using an active probe is recommended to avoid excessive loading. A passive probe might inhibit the 24 MHz oscillators from starting up. Use the following guidelines:

- RTC clock is running at 32.768 kHz.
- 24M\_XTALI/24M\_XTALO is running at 24 MHz (used for the PLL reference).

#### 4.5 Avoiding reset pitfalls

Follow the steps to ensure that you are booting correctly.

- 1. During initial power-on while asserting the POR\_B reset signal, ensure that 24 MHz and 32.768 kHz clock is active before releasing POR\_B.
- 2. Follow the recommended power-up sequence specified in the i.MX 8M Mini data sheet.
- 3. Ensure the POR\_B signal remains asserted (low) until all voltage rails associated with bootup are ON.

The SAI\_TXD[0:7], SAI\_RXD[0:7], BOOT\_MODE[0:1] balls and internal fuses control boot. For a more detailed description about the boot modes, see the system boot chapter in *i.MX 8M Mini Applications Processor Reference Manual* (document IMX8MMRM).

#### 4.6 Sample board bring-up checklist

The checklist in Table 39 incorporates the recommendations described in the previous sections. Blank cells should be filled in during the bring-up.

Table 39. Board bring-up checklist

No.	Checklist item	Details	Owner	Findings and Status			
The f	he following items must be completed serially.						
1	Perform a visual inspection	Check major components to make sure that nothing has been misplaced or rotated before powering ON.					
2	Verify all i.MX 8M Mini voltage rails	Confirm that the voltages match the data sheet's requirements. Be sure to check voltages as close to the i.MX 8M Mini as possible (like on a bypass capacitor). This reveals any IR drops on the board that could cause issues later. Ideally, all the i.MX 8M Mini voltage rails should be checked, but see guidance below for important rails to check for the i.MX 8M Mini.					
		VDD_SNVS, NVCC_SNVS, VDD_SOC, VDD_ARM, VDD_DRAM, NVCC_DRAM are particularly important voltages, and must fall within the parameters provided in the i.MX 8M Mini data sheet.					
3	Verify power-up sequence	Verify that power-on reset (POR_B) is deserted (high) after all power rails have come up and are stable. See the i.MX 8M Mini data sheet for details about power-up sequencing.					
4	Measure/probe input clocks (32.768 kHz, 24 MHz, others)	Without proper clocks, the i.MX 8M Mini does not function correctly.					

Table continues on the next page...

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Table 39. Board bring-up checklist (continued)

No.	Checklist item	Details	Owner	Findings and Status
5	Check JTAG connectivity	This is one of the most fundamental and basic access points to the i.MX 8M Mini to allow the debug and execution of low-level code, and probe/access processor memory.		
The f	ollowing items may be worked on in p	arallel with other bring-up tasks.		
-	Access internal RAM	Verify basic operation of the i.MX 8M Mini in system. The on-chip internal RAM starts at address 0x0090 0000 and is 128 kB in density. Perform a basic test by performing a write-readverify operation to the internal RAM. No software initialization is required to access internal RAM.		
-	Verify CLKO outputs (measure and verify default clock frequencies for desired clock output options) if the board design supports the probing of clock output balls.	This ensures that the corresponding clock is working and that the PLLs are working. This step requires chip initialization, for example, via the JTAG debugger, to properly set up the IOMUX to output clocks to I/O balls and to set up the clock control module to output the desired clock. See the chip reference manual for more details.		
-	Measure boot mode frequencies. Set the boot configure switch for each boot mode and measure the following (depending on system availability):  • NAND (probe CE to verify boot, measure RE frequency)  • SPI-NOR (probe slave select and measure clock frequency) MMC/SD (measure clock frequency)	This verifies the connectivity of signals between the i.MX 8M Mini and boot device and that the boot mode signals are properly set. See the "System Boot" chapter in the chip reference manual for details for boot mode configurations.		
-	Run basic DDR initialization and test memory	Assuming the use of a     JTAG debugger, run the     DDR initialization and open     a debugger memory window     pointing to the DDR memory     map-starting address.		

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#### Table 39. Board bring-up checklist (continued)

No.	Checklist item	Details	Owner	Findings and Status
		Try writing a few words     and verify if they can be     read correctly.		
		3. If not, recheck the DDR initialization sequence and whether the DDR has been correctly soldered onto the board. Users should recheck the schematic to ensure that the DDR memory has been connected to the i.MX 8M Mini correctly.		

# Chapter 5 Using Boundary Scan Description Language (BSDL) for board-level testing

#### 5.1 BSDL overview

The BSDL is used for board-level testing after the components are assembled. The interface for this test uses the JTAG pins. The definition is contained within IEEE Std 1149.1.

#### 5.2 How BSDL works

A BSDL file defines the internal scan chain, which is the serial linkage of the IO cells, within a particular device. The scan chain looks like a large shift register, which provides a means to read the logic level applied to a pin or to output a logic state on that pin. Using JTAG commands, the test tool uses the BSDL file to control the scan chain so that device-board connectivity can be tested.

For example, when using an external ROM test interface, the test tool does the following:

- 1. It outputs a specific set of addresses and controls to the pins connected to the ROM.
- 2. It performs a read command and scans out the values of the ROM data pins.
- 3. It compares the values read with the known golden values.

Based on this procedure, the tool determines whether the interface between the two parts is connected properly and does not contain shorts or opens.

#### 5.3 Downloading the BSDL file

The BSDL file for each i.MX processor is stored at NXP.com upon product release. Contact your local sales office or field applications engineer to check the availability of information before product releases.

#### 5.4 Pin coverage of BSDL

Each pin is defined as a port within the BSDL file. You can open the file with a text editor (such as Notepad or Wordpad) to review how each pin functions. The BSDL file defines following functions:

```
-- PORT DESCRIPTION TERMS
-- in = input only
-- out = three-state output (0, Z, 1)
-- buffer = two-state output (0, 1)
-- inout = bidirectional
-- linkage = OTHER (vdd, vss, analog)
```

#### NOTE

The appearance of a "linkage" in a pin's file means that this pin cannot be used with a boundary scan. These are usually power pins or analog pins that cannot be defined by a digital logic state.

#### 5.5 Boundary scan operation

When using the BSDL file to force the i.MX8MM, enter the boundary scan mode on the 8MMINILPD4 EVK:

- 1. COMPLIANCE\_PATTERNS of IMX8MM: entity is "(BOOT\_MODE0, BOOT\_MODE1, JTAG\_MOD, TEST\_MODE) (1101)". BOOT\_MODE0(G26)/ BOOT\_MODE1(G27) and TEST\_MODE(D26) should be high.
- 2. Set the SWITCH SW1101 [1-10]: at setting of 1111110001.

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- GPIO1\_IO02 is used as WDOG\_B in the EVK board design. This PIN should add 4.7 kilohms pull-up to NVCC\_GPIO1
  (install R106). Without the 4.7 kilohms pull-up resistor, this pin is floating when entering the boundary scan mode and
  may cause system reboot due to the watchdog RESET.
- 4. In the BSDL file, XTALI\_24M(B27)/XTALO\_24M(B25) "Pin name" does not match the data sheet because the JTAG1149 specification does not allow a number as the first character. The "Pin name" is an inversion in the BSDL file.

#### 5.6 I/O pin power considerations

The boundary scan operation uses each of the available device pins to drive or read values within a given system. Therefore, the power supply pin for each specific module must be powered for the IO buffers to operate. This is straightforward for the digital pins within the system.

NOTE				
The BSDL was only tested at 1.8 V				

### Chapter 6 Revision history

Table 40 summarizes the changes done to this document since the initial release.

Table 40. Revision history

Revision number	Date	Substantive changes	
3	12/2021	Replaced "PMIC" to     "PCA9450AAHN" across     the document	
		Updated Section i.MX 8M Mini power distribution block diagram to add the support of "PCA9450AAHN"	
		Updated Figure 20 to add the support of "PCA9450AAHN"	
		Added the footnote list "5" in Table 38 to add the support of "PCA9450AAHN"	
		Added Section     General recommendations	
		Editorial correction	
2	11/2020	Added checklist of DLL-off mode into Table 3 and Table 4.	
		Updated Section Boundary scan operation	
		Corrected board stack-up in Table 18 and Table 19	
		Added checklist of PMIC and inductor power rating into Table 8	
1	08/2019	Added Section Using Boundary Scan Description Language (BSDL) for board-level testing	
		Updated design recommendations for PMIC, QSPI, and JTAG in Design checklist table	
0	02/2019	Initial release	

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